

# **Low Power Analog Front End**

#### **■FEATURES**

 Supply Voltage +2.4 to +3.6V Low Current Consumption 4µA (OPA,OPB),

150µA (ADC)

 Low Noise Amplifier 1.3µVpp typ. (0.1 to 10Hz)

●Low Offset Voltage Amplifier 300µV max.

•RF immunity Amplifier

• Programmable Cell Bias Voltage

OPA: 0.3V to 1.7V (7 steps) OPB:

0.25V to 1.75V (50mV step) Programmable Gain Pre-Amplifier 1V/V to 8V/V

•High resolution Programmable Gain ADC

1V/V to 8V/V, 16-Bit (NFB), 32sps to 2k sps

System Calibration for offset & gain drift

Control external EEPROM as a Master device

 Ambient Operating Temperature -40°C to +85°C

I<sup>2</sup>C (3-Bit selectable slave address) Interface

Package EQFN-24-LE (4mm x 4mm)

#### **■GENERAL DESCRIPTION**

NJU9101 is a Low Power Analog Front End IC for use in micro-power sensing applications,

especially electrochemical sensors. It provides a complete signal processing solution between sensor and micro-processor as smart-sensor module.

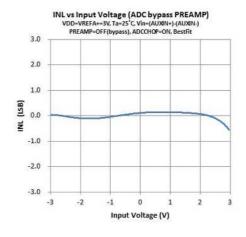
NJU9101 has 2 channel low power operational amplifiers. These amplifiers provide potentiostat and trans-impedance-amplifiers to constitute gas sensor systems. The NJU9101 has calibration circuit by using output data of built-in high precision ADC. It is suitable for temperature variation of sensor.

NJU9101 operates over voltage range of 2.4V to 3.6V. Total average current consumption can be less than 5μΑ.

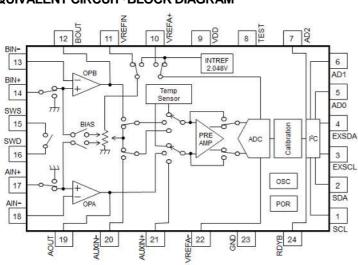
### **■APPLICATION**

- Gas Monitor
- Blood Glucose Meter
- Current Sensing Systems
- Low Power Systems
- Photodiode Sensing Systems
- Portable equipment

## ■INL vs Input Voltage (ADC)



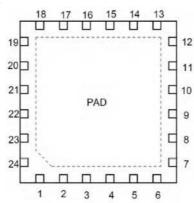
### **■EQUIVALENT CIRCUIT · BLOCK DIAGRAM**





### **■PIN CONFIGURATION**

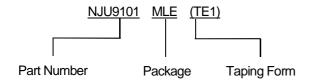
## EQFN-24-LE



PIN NO.	SYMBOL	DESC	RIPTION	Pin Type		
1	SCL	l <sup>2</sup> C serial	Digital Input			
2	SDA	l <sup>2</sup> C serial dat	a input / output	Digital Input / Output		
		`	an pull-up resistor)	Digital Impat/ Odipat		
3	EXSCL	'	t for external EEPROM	Digital Output		
	<u> </u>	` -	an pull-up register)	Digital Output		
4	EXSDA	-	tput for external EEPROM	Digital Input / Output		
		` .	an pull-up resister)			
5	AD0	Chip address selection input 0	Select 7 chip address from "000" to	Digital Input		
6	AD1	Chip address selection input 1	"110". Do not select address "111",	Digital Input		
7	AD2	Chip address selection input 2	which address is for production test purpose	Digital Input		
8	TEST	TEST terminal (This terminal is used	d for production test. Connect to VDD)	Analog Input		
9	VDD	Voltage	e Supply	Power Supply		
10	VREFA+	Positive voltage ref	erence input for ADC	Analog Input		
11	VREFIN	Voltage reference in	nput for Bias Registor	Analog Input		
12	BOUT	Voltage output	for Bch. OpAmp	Analog Output		
13	BIN-	Negative voltage ir	nput for Bch. OpAmp	Analog Input		
14	BIN+	Positive voltage in	put for Bch. OpAmp	Analog Input		
15	SWS	Switch So	ource Input 1	Swtich		
16	SWD	Switch D	rain Input 2	Swtich		
17	AIN+	Positive voltage in	put for Ach. OpAmp	Analog Input		
18	AIN-	Negative voltage ir	nput for Ach. OpAmp	Analog Input		
19	AOUT	Voltage output	for Ach. OpAmp	Analog Output		
20	AUXIN-	Auxiliary p	ositive input	Analog Input		
21	AUXIN+	Auxiliary n	egative input	Analog Input		
22	VREFA-	Negative voltage re	Negative voltage reference input for ADC			
	VINLI A	(connect to GND	Analog Input			
23	GND	G	GND			
24	RDYB	RDYB ou	RDYB output / GPIO			
PAD	EXPPAD	Exposed PAD on bac	kside (connect to GND)	GND		



### **■MARK INFORMATION**



#### **■ORDERING INFORMATION**

PART NUMBER	PACKAGE OUTLINE	RoHS	HALOGEN- FREE	TERMINAL FINISH	MARKING	WEIGHT (mg)	MOQ(pcs)
NJU9101MLE	EQFN-24-LE	0	0	Sn-2Bi	9101	31	1,000

#### **■ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	RATINGS	UNIT
Power Supply Voltage	$V_{DD}$	5	V
Analog Input Voltage <sup>(1)</sup>	$V_{IA}$	-0.3 to $V_{DD}$ +0.3 not exceeding 5	V
Digital Input Voltage	$V_{\text{ID}}$	-0.3 to 6	V
Switch Input Voltage <sup>(1)</sup>	V <sub>IS</sub>	-0.3 to $V_{DD}$ +0.3 not exceeding 5	V
On State Switch Current	I <sub>SO</sub>	-40 to +40 <sup>(3)</sup>	mA
Power Dissipation(T <sub>a</sub> =25°C) <sup>(2)</sup>	P <sub>D</sub>	830 <sup>(4)</sup> / 2100 <sup>(5)</sup> (2-layer / 4-layer)	mW
Operating Temperature Range	T <sub>opr</sub>	-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C

- (1): The input pins have clamp diodes to the power supply pins. Limit the input current to 10mA or less whenever input signals exceed the power supply rail by 0.3V.
- (2): Power dissipation is the power that can be consumed by the IC at  $T_a$ =25°C, and is the typical measured value based on JEDEC condition. When using the IC over  $T_a$ =25°C subtract the value [mW/°C] =  $P_D/T_{st}$  max.- 25) per temperature.
- (3): Mounted on glass epoxy board.

(101.5x114.5x1.6mm: based on EIA/JEDEC standard, 2Layers FR-4, with Exposed Pad)

(4): Mounted on glass epoxy board.

(101.5×114.5×1.6mm: based on EIA/JEDEC standard, 4Layers FR-4, with Exposed Pad)

(For 4Layers: Applying 99.5×99.5mm inner Cu area and a thermal via hole to a board based on JEDEC standard JESD51-5)

### **■RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	RATINGS	UNIT
Power Supply Voltage	$V_{DD}$	+2.4 to +3.6	V
Operating Temperature Range	T <sub>opr</sub>	-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C



### **■ELECTRICAL CHARACTERISTICS**

Unless otherwise specified, all limits ensured for  $T_a = 25$  °C,  $V_{DD} = V_{REFIN} = V_{REFA+} = 3V$ 

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
OPA, OPB							
Input Offset Voltage	V <sub>IO</sub>	$V_{ICM} = V_{DD}/2$ , $R_s = 50\Omega$	-	-	±300	μV	
Input Offset Voltage Drift	$\Delta V_{IO}/\Delta T$		-	±1	-	μV/°C	
Input Bias Current	I <sub>B</sub>		-	10	-	рА	
Open Loop Gain	$A_V$		-	100	-	dB	
Common Mode Rejection Ratio	CMR	$V_{ICM}$ = GND to 2V	65	80	-	dB	
Common Mode Input Voltage Range	$V_{ICM}$	CMR ≥ 65dB	GND	-	2	V	
Maximum Output Voltage	$V_{OH}$	$I_{SOUECE} = 1mA$	2.8	2.85	-	V	
waxiinum Ouput voitage	$V_{OL}$	$I_{SINK} = 1mA$	-	0.15	0.2	V	
Gain Band Width	GBW		-	30	-	kHz	
Slew Rate	SR		-	0.01	-	V/µs	
Equivalent Input Noise Voltage		$f = 100Hz$ , $R_S = 50\Omega$	-	50	-	nV/√Hz	
Equivalent input Noise voltage	e <sub>n</sub>	f = 0.1Hz to 10Hz	-	1.3	-	$\mu V_{pp}$	

Unless otherwise specified, all limits ensured for  $T_a$  = 25°C,  $V_{DD}$  =  $V_{REFIN}$  =  $V_{REFA+}$  = 3V, ADC reference Voltage = External

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
	OPA, OPB with BIASRES (Potentiostat)						
OPA referred to OPB Input Offset	V <sub>IO1A-B</sub>	OPA BIAS = 1V	_	_	±0.6	mV	
Voltage 1	V IO1A-B	OPB BIAS = 1V			<u> -</u> 0.0	1111	
OPA referred to OPB Input Offset	$\Delta V_{\text{IO1A-B}}$	OPA BIAS = 1V	_	±2	_	μV/°C	
Drift 1	/ ΔT	OPB BIAS = 1V	_	<del>1</del> 2	_	μν/ Ο	
OPA referred to OPB Input Offset		OPA BIAS = 1V	295	300	305	mV	
Voltage 2	V <sub>IO2A-B</sub>	OPB BIAS = 0.7V	293	300	303	IIIV	
OPA referred to OPB Input Offset	$\Delta V_{IO2A-B}$	OPA BIAS = 1V		. 5		\//oC	
Drift 2	/ ΔT	OPB BIAS = 0.7V	_	±5	-	μV/°C	
OPA referred to OPB Input Offset	\/	OPA BIAS = 1V	COE	600	FOF	m\/	
Voltage 3	V <sub>IO3A-B</sub>	OPB BIAS = 1.6V	-605	-600	-595	mV	
OPA referred to OPB Input Offset	$\Delta V_{IO3A-B}$	OPA BIAS = 1V		.0		\//oC	
Drift 3	/ ΔT	OPB BIAS = 1.6V	-	±8	-	μV/°C	

Unless otherwise specified, all limits ensured for  $T_a = 25$ °C,  $V_{DD} = V_{REFIN} = V_{REFA+} = 3V$ 

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PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Analog Switch (ANASW)						
On State Resistance	R <sub>ON</sub>	Analog Switch = ON $I_{DS}$ = -10mA		10	30	Ω
Off Leakage Current	I <sub>LOFFD</sub>	Analog Switch = OFF $V_{SWS}=2V/1V,$ $V_{SWD}=1V/2V$	1	±1	1	nA



Unless otherwise specified, all limits ensured for  $T_a = 25$ °C,  $V_{DD} = V_{REFIN} = V_{REFA+} = 3V$ , Temperature Input Mode

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Temperature Sensor						
Temperature Accuracy (Error) 1	T <sub>ACC1</sub>	$T_a = 25$ °C	-	±1	±5	°C
Temperature Accuracy (Error) 2	T <sub>ACC2</sub>	$T_a = -40$ °C to +85°C	-	±3	-	°C
Temperature Resolution	T <sub>RES</sub>		-	0.25	-	°C

Unless otherwise specified, all limits ensured for  $T_a = 25$ °C,  $V_{DD} = 3V$ 

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Internal Reference						
Internal Reference Voltage	$V_{IREF}$	±1%	2.028	2.048	2.068	V
Internal Reference Drift	$\Delta V_{IREF}$ / $\Delta T$	$T_a = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	-	30	-	ppm/°C

Unless otherwise specified, all limits ensured for  $T_a = 25$ °C,  $V_{DD} = V_{REFIN} = V_{REFA+} = 3V$ , Auxiliary Differential Input Mode

REFIN REFAT OUT TO THE STATE OF						
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
PREAMP						
PREAMP Gain Error	G	PREAMP Gain =		±0.1	-	%
FREAIVIF GAILI EITOI	$G_{ACCP}$	1V/1V to 8V/V	-	±0.1		/0
		PREAMP Gain = 1V/V				
PREAMP Common Mode Rejection	CMR <sub>PRE</sub>	AUXIN+ = AUXIN- =	70	90	-	dB
		GND+0.05 to $V_{DD}$ -1				
PREAMP Common Mode	\/	PREAMP Gain = 1V/V	GND		\/ 1	\/
Input Voltage	V <sub>ICMP</sub>	CMR <sub>PRE</sub> ≥ 70dB	+0.05	1	V <sub>CC</sub> -1	٧

Unless otherwise specified, all limits ensured for  $T_a = 25$ °C,  $V_{DD} = V_{REFIN} = V_{REFA+} = 3V$ , Auxiliary Input Mode ADC Chopping = ON, ADC Reference Voltage = External, ADC Gain = 1V/V, ADC Decimation Ratio = "320"

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
ADC					•	
Resolution	N	No missing code <sup>(6)</sup>	16	-	-	Bit
Noise Free Bit	NFB		-	16	-	Bit
Conversion Time	DR	See p.22 "ADC Conversion Time"	1	-	-	SPS
Output Noise	$V_{nADC}$	VREFA+=3V	1	13.9	-	μVrms
Integral Non Linearity	INL		-	±1	-	LSB
Gain Error		ADC Gain = 1V/1V to 8V/1V	-	±0.1	-	%
Offset Error		AUXIN+= AUXIN-= V <sub>DD</sub> /2	1	±1	-	LSB
Differential Input Voltage Range	V <sub>IDADC</sub>	V <sub>REF</sub> =  (VREFA+)-(VREFA-)	ı	±V <sub>REF</sub>	-	V
ADC Common Mode Rejection	CMR <sub>ADC</sub>	AUXIN+= AUXIN-= GND to V <sub>DD</sub>	80	90	-	dB
ADC Common Mode Input Voltage Range	V <sub>ICADC</sub>	CMR <sub>ADC</sub> ≥80dB	GND	-	V <sub>DD</sub>	V



(6) This Parameter is not production tested, please refer Typical Characteristics.

Unless otherwise specified, all limits ensured for  $T_a = 25$ °C,  $V_{DD} = V_{REFIN} = V_{REFA+} = 3V$ 

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Power Supply / OSC						
Voltage Range	$V_{DD}$		2.4	-	3.6	V
Bias Resistance	R <sub>BIAS</sub>		-	1.5	-	ΜΩ
Supply Current 1	I <sub>DD1</sub>	All Circuit Block Off	-	0.5	1	μA
Supply Current 2	I <sub>DD2</sub>	OPA, OPB	-	4	5.5	μA
Supply Current 3	I <sub>DD3</sub>	Internal Reference Voltage (2.048V)	-	31	40	μΑ
Supply Current 4	I <sub>DD4</sub>	PREAMP	-	55	75	μA
Supply Current 5	I <sub>DD5</sub>	ADC	-	150	200	μA
OSC Frequency	f <sub>OSC</sub>	±10%	276	307	338	kHz



# ■CHARACTERISTICS OF I/O STAGES FOR I<sup>2</sup>C-BUS Compatible (SDA, SCL)

I<sup>2</sup>C BUS Load Conditions

STANDARD MODE: Pull up resistance  $4k\Omega$  (Connected to  $V_{DD}$ ), Load capacitance 200pF (Connected to GND) FASE MODE: Pull up resistance  $4k\Omega$  (Connected to  $V_{DD}$ ), Load capacitance 50pF (Connected to GND)

PARAMETER	SYM	SYM Standard Mode				Fast Mod	ast Mode		
PARAIVIETER	BOL	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	UNIT	
Low Level Input Voltage	$V_{IL}$	0.0	-	$0.3V_{DD}$	0.0	-	1.5	V	
High Level Input Voltage	V <sub>IH</sub>	$0.7V_{DD}$	-	5.5	2.7	-	5.5	V	
Low Level Output Voltage	V <sub>OL</sub>	0		0.4	0	_	0.4	V	
(3mA at SDA pin)	V OL	U	_	0.4	U	_	0.4		
Input current each I/O pin with an input voltage		-10		10	-10	_	10		
between $0.1V_{DD}$ and $0.9V_{DD}$ max.	li I	-10	_	10	-10	_	10	μΑ	

# ■CHARACTERISTICS OF BUS LINES (SDA, SCL) FOR I<sup>2</sup>C-BUS Compatible Devices

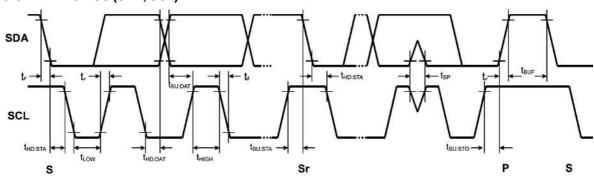
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STANDARD MODE: Pull up resistance  $4k\Omega$  (Connected to  $V_{DD}$ ), Load capacitance 200pF (Connected to GND) FASE MODE: Pull up resistance  $4k\Omega$  (Connected to  $V_{DD}$ ), Load capacitance 50pF (Connected to GND)

DADAMETED	SYM	Sta	ndard Mo	ode		Fast Mod	de	LINUT
PARAMETER	BOL	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	UNIT
SCL clock frequency	f <sub>SCL</sub>	10	-	100	10	-	400	kHz
Hold time (repeated) START condition	t <sub>HD:STA</sub>	4.0	-	-	0.6	-	1	μs
Low period of the SCL clock	t <sub>LOW</sub>	4.7	-	-	1.3	-	1	μs
High period of the SCL clock	t <sub>HIGH</sub>	4.0	-	-	0.6	-	1	μs
Set-up time for a repeated START condition	t <sub>SU:STA</sub>	4.7	-	-	0.6	-	-	μs
Data hold time	t <sub>HD:DAT</sub>	0	-	-	0	-	1	μs
Data set-up time	t <sub>SU:DAT</sub>	250	-	-	100	-	1	ns
Rise time of both SDA and SCL signals	t <sub>r</sub>	-	-	1000	-	-	300	ns
Fall time of both SDA and SCL signals	t <sub>f</sub>	-	-	300	-	-	300	ns
Set-up time for STOP condition	t <sub>SU:STO</sub>	4.0	-	-	0.6	-	-	μs
Bus free time between a STOP and START condition	t <sub>BUF</sub>	4.7	-	-	1.3	-	-	μs
Capacitive load for each bus line	C <sub>b</sub>	-	-	400	-	-	400	pF
Noise margin at the Low Level	$V_{nL}$	0.5	-	-	0.5	-		V
Noise margin at the High Level	$V_{nH}$	1	-	-	1	-	-	V

 $C_{\mbox{\scriptsize b}}$ : Total capacitance of one bus line in pF.

# ■TIMING ON THE I<sup>2</sup>C BUS (SDA, SCL)





# ■CHARACTERISTICS OF I/O STAGES FOR EEPROM I<sup>2</sup>C-BUS (EXSDA, EXSCL)

I<sup>2</sup>C BUS Load Conditions

Pull up resistance  $4k\Omega$  (Connected to  $V_{DD}$ ), Load capacitance 50pF (Connected to GND)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Low Level Input Voltage	$V_{IL}$	0.0	1	$0.3V_{DD}$	V
High Level Input Voltage	V <sub>IH</sub>	$0.7V_{DD}$	1	-	V
Low Level Output Voltage	\/	0	_	0.4	V
(3mA at SDA pin)	V <sub>OL</sub>	O		0.4	
Input current each I/O pin with an input	ı	10		10	
voltage between $0.1V_{DD}$ and $0.9V_{DD}$ max.	l <sub>i</sub>	-10	-	10	μΑ

### ■CHARACTERISTICS OF BUS LINES (EXSDA, EXSCL)

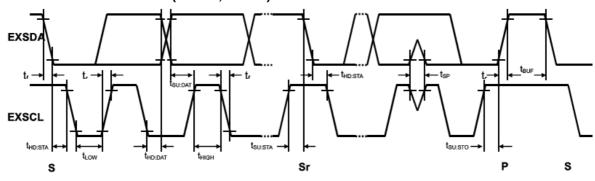
I<sup>2</sup>C BUS Load Conditions

Pull up resistance  $4k\Omega$  (Connected to  $V_{DD}$ ), Load capacitance 50pF (Connected to GND)

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PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
EXSCL clock frequency	f <sub>SCL</sub>	92	102.3	112.7	kHz
Hold time (repeat) START condition	t <sub>HD:STA</sub>	7.2	6.5	5.9	μs
Low period of the EXSCL clock	t <sub>LOW</sub>	7.2	6.5	5.9	μs
High period of the EXSCL clock	t <sub>HIGH</sub>	3.6	3.3	3.0	μs
Set-up time for a repeated START condition	t <sub>SU:STA</sub>	7.2	6.5	5.9	μs
Data hold time (EXSDA input)	t <sub>HD:DAT</sub>	0	-	-	μs
Data hold time (EXSDA output)	t <sub>HD:DAT</sub>	7.2	6.5	5.9	μs
Data Set-up time (EXSDA input)	t <sub>SU:DAT</sub>	0	-	-	μs
Data Set-up time (EXSDA output)	t <sub>SU:DAT</sub>	7.2	6.5	5.9	μs
Rise time of both SDA and SCL signals	t <sub>r</sub>	-	-	300	ns
Fall time of SDA and SCL signals	t <sub>f</sub>	-	-	300	ns
Set-up time for STOP condition	t <sub>su:sto</sub>	7.2	6.5	5.9	μs
Bus free time between a STOP and START condition	t <sub>BUF</sub>	7.2	6.5	5.9	μs
Capacitive load for each bus line	C <sub>b</sub>	-	-	400	pF
Noise margin at the Low level	V <sub>nL</sub>	0.5	-	-	V
Noise margin at the High level	$V_{nH}$	1	-	-	V

C<sub>b</sub>: total capacitance of one bus line in pF.

## ■TIMING ON THE EEPROM I2C BUS (EXSDA, EXSCL)





### **■REGISTER DESCRIPTION**

NJU9101 has register (list shown below) which can access it through I<sup>2</sup>C bus.

It can control the external EEPROM address corresponding to each register address from NJU9101.

REGISTER	EEPROM	REGISTER				Е	П				
ADDRESS	ADDRESS	NAME	D7	D6	D5	D4	D3	D2	D1	D0	
0x00	-	CTRL	-	RST	SENS	6CK [1:0]	MEAS	MEAS_S	SEL [1:0]	MEAS_SC	
0x01	-	STATUS	-	-	BOOT	CLKRUN	RDYB	OV	CERR	OFOV	
0x02	-	AMPDATA0		•		AMPDA	TA [15:8]		•		
0x03	-	AMPDATA1				AMPD/	ATA [7:0]				
0x04	-	AUXDATA0				AUXDA	TA [15:8]				
0x05	-	AUXDATA1				AUXDA	ATA [7:0]				
0x06	-	TMPDATA0				TMPDA	ATA [9:2]				
0x07	-	TMPDATA1	TMPDA	ATA [1:0]	-	-	-	-	-	-	
0x08	-	ID				ID	[7:0]				
0x09	-	ROMADR0	-	-	-	-	-		ROMADR [10	:8]	
0x0A	-	ROMADR1				ROMA	DR [7:0]				
0x0B	-	ROMDATA				ROMDA	ATA [7:0]				
0x0C	-	ROMCTRL	-	-	ROMERR	ROMBUSY	ROMSTOP	ROMACT	ROMN	/ODE [1:0]	
0x0D	-	TEST				TES	Γ [7:0]				
0x0E	0x000	ANAGAIN	-	-	-	-	PRE_G	AIN [1:0]	ADC_	GAIN [1:0]	
0x0F	0x001	BLKCONN0	-	BIASSWA BIASSWB PRE_BIAS							
0x10	0x002	BLKCONN1		OPA_BIAS [2:0	)]		(	OPB_BIAS [4:0]			
0x11	0x003	BLKCONN2	PREMODE	INPSWA	INPSWB	ANASW	BIASSWN	PAMPSEL	BIASSEL	VREFSEL	
0x12	0x004	BLKCTRL				BLKCT	RL [7:0]				
0x13	0x005	ADCCONV	-	ADCCHOP	CLKE	OIV [1:0]	REJ	[1:0]	08	SR [1:0]	
0x14	0x006	SYSPRESET	RDYBOE	RDYBDAT	RDYBM	10DE [1:0]	-	-	-	AMPAUX	
0x15	0x007	SCAL1A0	-	-	-	-	-	-	-	SCAL1A [8]	
0x16	0x008	SCAL1A1				SCAL	1A [7:0]				
0x17	0x009	SCAL2A0	-	-	-	-	•	-	-	SCAL2A [8]	
0x18	0x00A	SCAL2A1				SCAL	2A [7:0]				
0x19	0x00B	SCAL3A0	-	-	-	-	-	-	-	SCAL3A [8]	
0x1A	0x00C	SCAL3A1				SCAL	3A [7:0]				
0x1B	0x00D	SCAL4A0	-	-	-	-	1	-	-	SCAL4A [8]	
0x1C	0x00E	SCAL4A1				SCAL	4A [7:0]				
0x1D	0x00F	SCAL1B0				SCAL1	B [15:8]				
0x1E	0x010	SCAL1B1				SCAL	1B [7:0]				
0x1F	0x011	SCAL2B0		SCAL2B [15:8]							
0x20	0x012	SCAL2B1	SCAL2B [7:0]								
0x21	0x013	SCAL3B0				SCAL	BB [15:8]				
0x22	0x014	SCAL3B1	SCAL3B [7:0]								
0x23	0x015	SCAL4B0	SCAL4B [15:8]								
0x24	0x016	SCAL4B1	SCAL4B [7:0]								
0x25	0x017	OCAL1A0	OCAL1A [						L1A [9:8]		
0x26	0x018	OCAL1A1		•		OCAL	1A [7:0]		•		



0x27	0x019	OCAL2A0	-	-	-	-	-	-	OCAL2A [9:8]		
0x28	0x01A	OCAL2A1		OCAL2A [7:0]							
0x29	0x01B	OCAL3A0	-	-	-	-	-	-	OCAL3A [9:8]		
0x2A	0x01C	OCAL3A1		OCAL3A [7:0]							
0x2B	0x01D	OCAL4A0	-	OCAL4A [							
0x2C	0x01E	OCAL4A1				OCAL <sup>4</sup>	4A [7:0]		•		
0x2D	0x01F	OCAL1B0	-				OCAL1B [14:8]				
0x2E	0x020	OCAL1B1				OCAL	1B [7:0]				
0x2F	0x021	OCAL2B0	-				OCAL2B [14:8]				
0x30	0x022	OCAL2B1				OCAL	2B [7:0]				
0x31	0x023	OCAL3B0	-				OCAL3B [14:8]				
0x32	0x024	OCAL3B1				OCAL	3B [7:0]				
0x33	0x025	OCAL4B0	-				OCAL4B [14:8]				
0x34	0x026	OCAL4B1				OCAL	4B [7:0]				
0x35	0x027	SCAL1				SCAL	.1 [7:0]				
0x36	0x028	SCAL2				SCAL	2 [7:0]				
0x37	0x029	SCAL3				SCAL	.3 [7:0]				
0x38	0x02A	OCAL1				OCAL	1 [7:0]				
0x39	0x02B	OCAL2				OCAL	2 [7:0]				
0x3A	0x02C	OCAL3				OCAL	.3 [7:0]				
0x3B	0x02D	AUXSCAL0		AUX_SCAL [15:8]							
0x3C	0x02E	AUXSCAL1		AUX_SCAL [7:0]							
0x3D	0x02F	AUXOCAL0		AUX_OCAL [15:8]							
0x3E	0x030	AUXOCAL1		AUX_OCAL [7:0]							
0x3F	-	CHKSUM				CHKSL	JM [7:0]				



## **■EVERY REGISTER DESCRIPTION**

**CTRL** Register

Register Address: 0x00, EEPROM Address: -

	CTRL									
BIT	[7]	[6]	[5] [4]		[3]	[2] [1]		[0]		
BIT NAME	-	RST	SENSCK [1:0]		MEAS	MEAS_SEL [1:0]		MEAS_SC		
R/W	-	WS	R'	RW		RW		RW		
RESET	-	-	0:	<b>(</b> 0	0	0	x0	0		

BIT	BIT NAME	FUNCTION
[6]	RST	Write Software Reset. When read this bit, always return "0".  0: No effect 1: Reset
[5:4]	SENSCK	Change offset voltage of OPB to check sensor diagnostic.  00: OFF (No change) 01: Plus Offset (Change Offset Voltage ≈ +5.0mV) 10: Minus Offset (Change Offset Voltage ≈ -5.0mV) 11: Reserve
[3]	MEAS	Measurement Switch When write "1", ADC conversion starts. When read this bit, returns "1" in case of under conversion, "0" in case of idle condition. When select "Single Conversion" mode, this bit is set to "0" automatically after conversion completion. When select "Continuous Conversion" mode and write "0", ADC conversion stop and return to an idol state.  O: Measurement OFF (Operating condition of this chip follows "BLKCTRL" condition)  1: Measurement ON
[2:1]	MEAS_SEL	Measurement Mode Selection.  00: Temperature sensor input mode 01: Amplifier input mode 10: Auxiliary input mode 11: Reserve
[0]	MEAS_SC	Measurement Mode for ADC  0: Single Conversion  1: Continuous Conversion



## **STATUS Register**

Register Address: 0x01, EEPROM Address: -

	STATUS								
BIT	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]	
BIT NAME	-	ı	BOOT	CLKRUN	RDYB	OV	CERR	OFOV	
R/W	-	-	R	R	R	R	R	R	
RESET	-	-	1	-	1	0	0	0	

BIT	BIT NAME	FUNCTION
[5]	воот	Booting flag for IC.  NJU9101 reads initial register value from external EEPROM as booting.  This bit returns "1" until the reading of the initial register value is completed from start.  0: Completion of booting  1: Under booting
[4]	CLKRUN	System Clock Condition.  0: System Clock is sleeping 1: System Clock is operating
[3]	RDYB	Data Ready Flag. When conversion data is updated, this bit is cleared to "0".  When either "AMPDATA0", "AUXDATA0", or "TMPDATA" is read, this bit is set to "1".  0: New ADC data is ready  1: New ADC data is not ready
[2]	OV	Overflow flag in sensitivity calibration of ADC output data.  When over flow is occurred in sensitivity calibration of ADC conversion data, this bit is set to "1". When this bit is "1", ADC output data ("AMPDATA" or "AUXDATA") is set to 0x7FFF (positive over flow) or 0x8000 (negative over flow). When either "AMPDATA0", "AUXDATA0", or "TMPDATA" is read, this bit is cleared to "0".  0: ADC conversion data is valid 1: ADC conversion data is over flow (set 0x7FFF or 0x8000)
[1]	CERR	Overflow flag in calibration coefficient data.  When over flow is occurred in setting of calibration coefficient data, this bit is set to "1". In case of "1", ADC output data is invalid value.  When either "AMPDATAO", "AUXDATAO" or "TMPDATA" is read, this bit is cleared to "0".  0: No overflow in calibration coefficient calculation  1: Overflow in calibration coefficient calculation (Output data is invalid)
[0]	OFOV	Overflow flag in offset calibration of ADC output data.  When over flow is occurred in offset calibration of ADC conversion data, this bit is set to "1".  In case of "1", ADC output data is invalid value.  When either "AMPDATAO", "AUXDATAO" or "TMPDATA" is read, this bit is cleared to "0".  O: No overflow in offset calibration data  1: Overflow in offset calibration data (Output data is invalid)



## AMPDATA0 / AMPDATA1 Register

Register Address: 0x02 / 0x03, EEPROM Address: -

		AMPDATA0									AMPDATA1						
	Register Address: 0x02									Register Address: 0x03							
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0] [7] [6] [5] [4] [3] [2] [1]									[0]						
BIT NAME							Α	MPDA	TA [15:	0]							
R/W		R															
RESET									-								

BIT	BIT NAME	FUNCTION
AMPDATA0 [7:0] + AMPDATA1 [7:0]	AMPDATA[15:0]	ADC output data register for amplifier input mode. Singed 16-Bit data.

## **AUXDATA0 / AUXDATA1 Register**

Register Address: 0x04 / 0x05, EEPROM Address: -

7107127117107	to / / to / Ext. / to gisto!								ogioto.	, .aa. oc		., одос	, <u> </u>		, .aa. 00	<u> </u>
		AUXDATA0							AUXDATA1							
	Register Address: 0x04							Register Address: 0x05								
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0] [7] [6] [5] [4] [3] [2] [1] [0]									[0]					
BIT NAME							Α	UXDA	TA [15:	0]						
R/W		R														
RESET									-							

BIT	BIT NAME	FUNCTION
AUXDATA0 [7:0] + AUXDATA1 [7:0]	AUXDATA[15:0]	ADC output data register for Auxiliary input mode. Signed 16-Bit data.

## TMPDATA0 / TMPDATA1 Register

Register Address: 0x06 / 0x07, EEPROM Address: -

				TMPD	OATA0						TMPDATA1					
	Register Address: 0x06								Register Address: 0x07							
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0]						[0]	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]
BIT NAME		TMPDATA [9:0]									-	-	-	-	-	-
R/W		R.W								-						
RESET						-					-	-	-	-	-	-

ビット	ビット名	機能
		ADC output data register for Temperature sensor input mode.
TMPDATA0 [7:0]		Signed 8.2 fixed point format. (-45°C to +127.75°C)
+	TMPDATA[9:0]	Temperature calibration calculation is executed by value of TEMPDATA.
TMPDATA1 [7:6]		When calibration is executed by using external temperature sensor, write data
		which getting from external temperature sensor to this register.



## **ID Register**

Register Address: 0x08, EEPROM Address: -

				ID					
BIT	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]	
BIT NAME		ID [7:0]							
R/W		R							
RESET		0x55							

BIT	BIT NAME	FUNCTION
[7:0]	ID	Fixed value "0x55" is stored as a chip identification code in this register.

## ROMADR0/ROMADR1 Register

Register Address: 0x09 / 0x0A, EEPROM Address: -

		ROMADR0							ROMADR1							
	Register Address: 0x09						Register Address: 0x0A									
BIT	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]
BIT NAME	-	-	-	-	-	ROMADR [10:0]										
R/W	-	-	-	-	-						RW					
RESET	-	-	-	-	-						0x0					

ビット	ビット名	機能
ROMADR0 [2:0]		
+	ROMADR[10:0]	This is EEPROM address selection register that read/write from/to EEPROM.
ROMADR1 [7:0]		

<sup>\*</sup>Be sure to set ROMADR0[4:3] = "00" to control EEPROM.

# **ROMDATA Register**

Register Address: 0x0B, EEPROM Address: -

				ROMDATA						
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0]								
BIT NAME		ROMDATA [7:0]								
R/W		RW								
RESET		0x00								

BIT	BIT NAME	FUNCTION
[7:0]	ROMDATA	In read mode, return a reading data from EEPROM.
[7.0]	[7:0] ROMDATA	In write mode, set a writing data to EEPROM.

<sup>\*</sup>Be sure to set ROMADR0[4:3] = "00" to control EEPROM.



## **ROMCCTL Register**

Register Address: 0x0C, EEPROM Address: -

				ROMCCTL				
BIT	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]
BIT NAME	-	-	ROMERR	ROMBUSY	ROMSTOP	ROMACT	ROMMO	DDE [1:0]
R/W	-	-	RC	R	WS	WS	W	
RESET	-	-	-	-	0x0	0x0	0x0	

BIT	BIT NAME	FUNCTION
[5]	ROMERR	When I <sup>2</sup> C bus communication error occurs during accessing to external EEPROM, this bit is set to "1". It is communication error in the following cases,  1) When NJU9101 outputs address, data, acknowledge data, it receives the EXSDA data different from the EXSDA data which outputs.  2) NJU9101 receives NACK response in the timing which it is expected to receive ACK response.  And, It is cleared to "0" when this bit is written in "1".  0: I2C communication is not error  1: I2C communication is error
[4]	ROMBUSY	This bit shows accessing status to external EEOPROM.  0: Completion of the access 1: Under accessing
[3]	ROMSTOP	When write "1" to "ROMSTOP" bit, stop accessing to external EEPROM. "ROMBUSY" bit is cleared to "0" immediately. When it stops accessing during writing to external EEPROM, ROM data is not guaranteed. In the read mode, this bit always returns "0".  1: stop accessing to external EEPROM
[2]	ROMACT	When write "1" to ROMACT bit, start accessing to external EEPROM with following "ROMMODE[1:0]" data. In write "0" case, it is not started accessing.  And, to start accessing to external EEPROM, it is necessary that it is not accessing timing to external EEPROM ("ROMBUSY" bit = "0"), and system clock is during operation ("CLKRUN" bit = "1"). In the read mode, this bit always returns "0".  1: start accessing to external EEPROM
[1:0]	ROMMODE	<ul> <li>Write operation for external EEPROM. In the read mode, this bit returns "0".</li> <li>00: Read one byte data from external EEPROM (address ROMADR[10:0]), and, store this one byte data to ROMDATA[7:0] bit register in NJU9101.</li> <li>01: Write ROMDATA[7:0] bit data to register in external EEPROM which is assigned by ROMADR[10:0] address.</li> <li>10: Load external EEPROM data to Host-register (ex. MPU)</li> <li>11: Store Host-register setting (ex. MPU) into external EEPROM data.</li> </ul>

<sup>\*</sup>Be sure to set ROMADR0[4:3] = "00" to control EEPROM.



## **TEST Register**

Register Address: 0x0D, EEPROM Address: -

	TEST								
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0]							
BIT NAME		TEST [7:0]							
R/W		RW							
RESET				0x	00				

<sup>\*</sup>This register if for production test purpose. Do not write data to this register.

## **ANAGAIN Register**

Register Address: 0x0E, EEPROM Address: 0x000

				ANAGAIN				
BIT	[7]	[6]	[5]	[4]	[3] [2]		[1]	[0]
BIT NAME	-	-	-	-	PRE_GAIN [1:0] ADC_G		ADC_G	AIN [1:0]
R/W	-	-	-	-	RW R'		W	
RESET	-	-	-	-	0x0 0x0		к0	

BIT	BIT NAME	FUNCTION
[3:2]	PRE_GAIN	Pre-amplifier gain selection  00: 1 V/V 01: 2 V/V 10: 4 V/V 11: 8 V/V
[1:0]	ADC_GAIN	Programmable-gain-amplifier in ADC selection  00: 1 V/V  01: 2 V/V  10: 4 V/V  11: 8 V/V



## **BLKCONNO** Register

Register Address: 0x0F, EEPROM Address: 0x001

	BLKCONN0							
BIT	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]
BIT NAME	-	-	BIASSWA	BIASSWB	PRE_BIAS [3:0]			
R/W	-	-	RW	RW	RW			
RESET	-	-	0x0	0x0		0:	<b>κ</b> 0	

BIT	BIT NAME	FUNCTION
[5]	BIASSWA	This is Switch for connecting "BIASRES" and "OPA positive input"
		<ul><li>00: Open "BIASRES" and "OPA positive input"</li><li>01: Connect "BIASRES" and "OPA positive input"</li></ul>
		This is Switch for connecting "BIASRES" and "OPB positive input"
[4]	BIASSWB	<ul><li>00: Open "BIASRES" and "OPB positive input"</li><li>01: Connect "BIASRES" and "OPB positive input"</li></ul>
[3:0]	PRE_BIAS	Negative input bias level for PREAMP (From 0.3V to 1.7V are 100mV steps)  This bias level is set by "BIASRES" Circuit Block.  V <sub>REFIN</sub> = 3V or at INTVREF(2.048V) as follows 0000: GND 0001: 0.3V 0010: 0.4V 0011: 0.5V : : 1101: 1.5V 1110: 1.6V 1111: 1.7V



## **BLKCONN1** Register

Register Address: 0x10, EEPROM Address: 0x002

	BLKCONN1							
BIT	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]
BIT NAME	OPA_BIAS [2:0]			OPB_BIAS [4:0]				
R/W	RW					RW		
RESET	RESET 0x0					0x0		

BIT	BIT NAME	FUNCTION
[7:5]	OPA_BIAS	Bias Level for OPA, This bias level is set by "BIASRES" Block.  V <sub>REFIN</sub> = 3V or at INTVREF(2.048V) as follows 000: GND 001: 0.3V 010: 0.5V 011: 0.7V 100: 1.0V 101: 1.3V 110: 1.5V 111: 1.7V
[4:0]	OPB_BIAS	Bias Level for OPB (From 0.25V to 1.75V are 50mV steps).  V <sub>REFIN</sub> = 3V or at INTVREF(2.048V) as follows 00000: GND 00001: 0.25V 00010: 0.3V 00011: 0.35V : 11101: 1.65V 11110: 1.7V 11111: 1.75V



## **BLKCONN2** Register

Register Address: 0x11, EEPROM Address: 0x003

	BLKCONN2							
BIT	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]
BIT NAME	PREMODE	INPSWA	INPSWB	ANASW	BIASSWN	PAMPSEL	BIASSEL	VREFSEL
R/W	RW	RW	RW	RW	RW	RW	RW	RW
RESET	0x0	0x0	0x0	0x0	0x0	0x0	0x0	0x0

BIT	BIT NAME	FUNCTION					
		Select PREAMP mode					
[7]	PREMODE	O. Non law arted Amerilian and de					
		<ul><li>0: Non-Inverted Amplifier mode</li><li>1: Instrumentation Amplifier mode</li></ul>					
		OPA positive input connection					
		or Appearate input confidence.					
[6]	INPSWA	0: GND Positive input is connected to GND.					
		1: AINP Positive input is connected to AINP Pin.					
		OPB positive input connection					
[5]	INPSWB						
		O: GND Positive input is connected to GND.  1: BINP Positive input is connected to BINP Pin.					
		BINP Positive input is connected to BINP Pin.  Build in Analog Switch Status					
		Build III 74 I alog Switch Status					
[4]	ANASW	0: Switch OFF					
		1: Switch ON On Resistance is 10Ω typ.					
		Absolute Maximum Input Current is ±50mA.					
		Select switch for PREAMP / ADC Negative Input at AMP / AUX input mode.					
[3]	BIASSWN	0: OPB Output / AUXIN-					
		1: BIASRES This is selectable bias level set by "PRE-BIAS".					
		Enable / Disable PREAMP for signal path.					
[0]	DAMDCEL						
[2]	PAMPSEL	0: Disable (Bypass PREAMP)					
		1: Enable					
		Reference Voltage selection for Bias Register					
[1]	BIASSEL	0: Internal Reference (2.048V)					
		1: External Reference					
-		Reference Voltage selection for ADC					
[0]	VDETOFI	, and the second					
[0]	VREFSEL	0: Internal Reference (2.048V)					
		1: External Reference					



**BLKCTRL** Register

Register Address: 0x12,	EEPROM Address: 0x004
-------------------------	-----------------------

	BLKCNT								
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0]							
BIT NAME		BLKCTRL [7:0]							
R/W		RW							
RESET				0x	00				

BIT	BIT NAME	FUNCTION					
[7:0]	BLKCTRL	Circuit Block Powered down selection.  When ADC is in the idle state, circuit block which this bit is set to "0" is automatically powered down.  The circuit block which this bit is set to "1" is kept powered on state even in case of ADC idle state. When all bits are "0", NJU9101 goes "power down mode" except for Digital block.  [7]: BIASRES block [6]: OPB block [5]: OPA block [4]: OSC block [3]: PREAMP block [2]: INTVREF(2.048V) block					
		[1]: ADC block [0]: Temperature Sensor block					



## **ADCCONV** Register

Register Address: 0x13, EEPROM Address: 0x005

	ADCCONV											
BIT	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]				
BIT NAME	-	ADCCHOP	CLKD	IV [1:0]	REJ	[1:0]	OSR	[1:0]				
R/W	-	RW	R	RW		W	RW					
RESET	-	0x0	0x0		0:	x0	0:	x0				

BIT	BIT NAME	FUNCTION
[6]	ADCCHOP	ADC CHOP Switch. It's effective in reducing offset Voltage of PREAMP and ADC. Reduce offset voltage by chopping input signal. When this bit is "1", conversion time becomes long. (ex. 16.2ms(ADCCHOP="0") -> 31.1ms(ADCCHOP="1"))  0: CHOP OFF 1: CHOP ON
[5:4]	CLKDIV	Select operation clock frequency for sigma-delta modulator. f <sub>OSC</sub> =307.2kHz typ.  00: f <sub>mod</sub> =(1/2) x f <sub>OSC</sub> 01: f <sub>mod</sub> =(1/4) x f <sub>OSC</sub> 10: f <sub>mod</sub> =(1/8) x f <sub>OSC</sub> 11: f <sub>mod</sub> =(1/16) x f <sub>OSC</sub>
[3:2]	REJ	Select rejection mode for Sinc3 filter  00: 50/60Hz Rejection  01: 50Hz Rejection  10: 60Hz Rejection  11: Reserved
[1:0]	OSR	Select Decimation ratio for Sinc3 filter.  Total Decimation Ratio is decided by REJ / OSC bits combination.



### **ADC Decimation Ratio**

		REJ [1:0]									
OSR [1:0]	00	01	10	11							
00	768	768	640	-							
01	384	384	320	-							
10	192	192	160	-							
11	96	96	80	-							

# ADC Conversion Time [ms]

OSR		REJ [1:0]														
[1:0]	00	01	10	11	00	01	10	11	00	01	10	11	00	01	10	11
00	16.2	16.2	13.7	-	31.3	31.3	26.3	-	5	5	4.2	-	15.3	15.3	12.8	-
01	8.7	8.7	7.5	-	16.3	16.3	13.8	-	2.5	2.5	2.1	-	7.8	7.8	6.5	-
10	5.0	5.0	4.3	-	8.8	8.8	7.6	-	1.3	1.3	1.0	•	4.0	4.0	3.4	-
11	3.1	3.1	2.8	1	5.1	5.1	4.5	-	0.6	0.6	0.5	ı	2.1	2.1	1.8	-
State	Single Conversion										Con	tinuous	Conver	rsion		
Sidle		CHOP: OFF CHOP: ON								CHO	P: OFF			CHOF	P: ON	

## Conversion Time vs Resolution (ADC)

ADC		CHO	P: ON		CHOP: OFF					
Conversion		ADC	Gain		ADC Gain					
Time	1V/V	2V/V	4 V/V	8 V/V	1 V/V	2 V/V	4 V/V	8 V/V		
26.3ms	16 / (16)	16 / (16)	16 / (16)	16 / (16)	16 / (16)	16 / (16)	15.6 / (16)	15.3 / (16)		
13.8ms	16 / (16)	16 / (16)	15.2 / (16)	16 / (16)	16 / (16)	16 / (16)	15 / (16)	14.8 / (16)		
7.6ms	15 / (16)	14.7 / (16)	14.5 / (16)	14 / (16)	15 / (16)	14.7 / (16)	14.1 / (16)	13.5 / (16)		
4.5ms	14 / (16)	14 / (16)	13.5 / (16)	12 / (14.7)	14 / (16)	14 / (16)	13.6 / (16)	12 / (14.7)		

Noise Free Bit / (Effective Number of Bits), Unit: bit

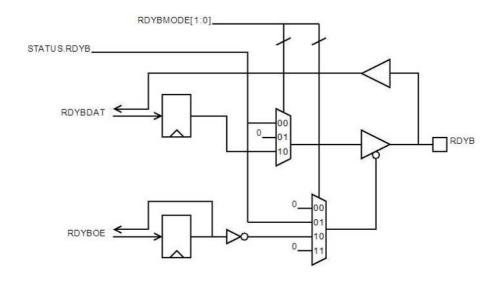


## **SYSPRESET Register**

Register Address: 0x14, EEPROM Address: 0x006

	SYSPRESET												
BIT	[7]	[6]	[6] [5] [4] [3] [2] [1] [0]										
BIT NAME	RDYBOE	RDYBDAT	RDYBMO	ODE [1:0]	-	1	-	AMPAUX					
R/W	RW	RW	R'	W	-		-	RW					
RESET	0x0	-	0)	κ1	-	1	-	0x0					

BIT	BIT NAME	FUNCTION
[7]	RDYBOE	RDYB terminal direction of GPIO mode  0: RDYB terminal is input mode  1: RDYB terminal is Output mode
[6]	RDYBDAT	Return RDYB terminal level in input mode. Store RDYB terminal level in Output mode.
[5:4]	RDYBMODE	Select function of RDYB terminal  00: RDYB terminal outputs "RDYB" bit in STATUS register.  01: RDYB terminal outputs "RDYB" bit in STATUS register.  with open-drain circuit style.  10: RDYB terminal is used as GPIO.  Output condition is set by "RDYBDAT" and "RDYBOE".  11: Reserved
[0]	AMPAUX	Select Calibration channel coefficient assignment.  O: AMPDATA uses SCAL/OCAL calibration coefficient.  AUXDATA uses AUX_SCAL / AUX_OCAL calibration coefficient.  1: AMPDATA uses AUX_SCAL / AUX_OCAL calibration coefficient.  AUXDATA uses SCAL/OCAL calibration coefficient.





## SCALxA0 / SCALxA1 Register

Register Address: 0x15 to 0x1C, EEPROM Address: 0x007 to 0x00E

			SC	ALxA0	(x=1 to	4)			SCALxA1 (x=1 to 4)							
		Register Address: 0x15, 0x17, 0x19, 0x1B								Register Address: 0x16, 0x18, 0x1A, 0x1C						
	EEPROM Address: 0x007, 0x009, 0x00B, 0x00D								DD EEPROM Address: 0x008, 0x00A, 0x00C, 0x00E						30E	
BIT	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0] [7] [6] [5] [4] [3] [2] [1] [0							[0]	
BIT NAME	-	-	-	-	-	-	-				SC	ALxA [	8:0]			
R/W	-	-	-	-	-	-	-	RW								
RESET	-	-	-	-	-	-	-	-								

BIT	BIT NAME	FUNCTION
SCALxA0 [0] + SCALxA1 [7:0]	SCALxA [8:0] (x=1 to 4)	1 <sup>ST</sup> order Gain Calibration parameter for AMPDATA. This parameter is signal 9-Bit data.

## SCALxB0/SCALxB1 Register

Register Address: 0x1D to 0x24, EEPROM Address: 0x00F to 0x016

		SCALxB0 (x=1 to 4)									SCALxB1 (x=1 to 4)						
		Register Address: 0x1D, 0x1F, 0x21, 0x23							Register Address: 0x1E, 0x20, 0x22, 0x24								
	EE	EEPROM Address: 0x00F, 0x011, 0x013, 0x15							EEPROM Address: 0x010, 0x012, 0x014, 0x016						016		
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0]								[6]	[5]	[4]	[3]	[2]	[1]	[0]	
BIT NAME								SCALx	B [15:0]								
R/W		RW															
RESET		-															

BIT	BIT NAME	FUNCTION
SCALxB0 [7:0] + SCALxB1 [7:0]	SCALxB [15:0] (x=1 to 4)	Zero-order Gain Calibration parameter for AMPDATA. This parameter is unsigned 16-Bit data.



## OCALxA0 / OCALxA1 Register

Register Address: 0x25 to 0x2C.	EEPROM Address: 0x017	to 0x01E

			OC	ALxA0	(x=1 to	o 4)			OCALxA1 (x=1 to 4)							
		R	egister	Addres	s: 0x2	5 to 0x2	28	Register Address: 0x29 to 0x2C								
		EEF	PROM.	Addres	s: 0x01	7 to 0x	01A	EEPROM Address: 0x01B to 0x01E								
BIT	[7]	[6]	[5]	[4]	[3]	[2] [1] [0] [7] [6] [5] [4] [3] [2] [1]							[0]			
BIT NAME	-	-	-	-	-	-					OCAL	κA [9:0]				
R/W	-	-	-	-	-	-	RW									
RESET	-	-	-	-	-	-	-									

BIT	BIT NAME	FUNCTION
OCALxA0 [1:0] + OCALxA1 [7:0]	OCALxA [9:0] (x=1 to 4)	1 <sup>ST</sup> order Offset Calibration parameter for AMPDATA. This parameter is signed 10-Bit data.

### OCALxB0/OCALxB1 Register

Register Address: 0x2D to 0x34, EEPROM Address: 0x01F to 0x026

			00	ALxB0	(x=1 to	o 4)			OCALxB1 (x=1 to 4)							
		Registe	er Addr	ess: 0x2	2D, 0x2	2F, 0x3	1, 0x33	3	Register Address: 0x2E, 0x30, 0x32, 0x34							
	EE	PROM	Addres	ss: 0x01	IF, 0x0	21, 0x0	)23, 0x(	025	EE	PROM	Addres	ss: 0x0	20, 0x0	22, 0x0	24, 0x0	)26
BIT	[7]	[6]	6] [5] [4] [3] [2] [1] [0]							[6]	[5]	[4]	[3]	[2]	[1]	[0]
BIT NAME	-							OC	ALxB [1	4:0]						
R/W	-		RW													
RESET	-		- · · · · · · · · · · · · · · · · · · ·													

BIT	BIT NAME	FUNCTION
OCALxB0 [6:0] + OCALxB1 [7:0]	OCALxB [14:0] (x=1 to 4)	Zero-order Offset Calibration parameter for AMPDATA. This parameter is signed 15-Bit data.

## **SCALx Register**

Register Address: 0x35 to 0x37, EEPROM Address: 0x027 to 0x029

	SCALx (x=1 to 3)											
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0]										
BIT NAME		SCALx [7:0]										
R/W		RW										
RESET		-										

BIT	BIT NAME	FUNCTION
[7:0]	SCALx (x=1 to 3)	Threshold Temperature for AMPDATA Sensitivity Calibration.  Signed 8.0 fixed point format. (-45°C to +127°C)  -45°C ≤ SCAL1 < SCAL2 < SCAL3 ≤ +127°C



**OCALx Register** 

Register Address: 0x38 to 0x3A, EEPROM Address: 0x02A to 0x02C

	OCALx (x=1 to 3)											
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0]										
BIT NAME		OCALx [7:0]										
R/W		RW										
RESET		-										

BIT	BIT NAME	FUNCTION
[7:0]	OCALx (x=1 to 3)	Threshold Temperature for AMPDATA Offset Calibration.  Signed 8.0 fixed point format. (-45°C to +127°C)  -45°C ≤ OCAL1 < OCAL2 < OCAL3 ≤ +127°C

AUX\_SCAL0 / AUX\_SCAL1 Register

Register Address: 0x3B / 0x3C, EEPROM Address: 0x02D / 0x02E

		<u>-</u>								,	,					
				AUX_S	SCAL0				AUX_SCAL1							
			Regi	ster Ad	dress:	0x3B			Register Address: 0x3C							
		EEPROM Address: 0x02D									EEPR	OM Ac	ldress:	0x02E		
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0]								[6]	[5]	[4]	[3]	[2]	[1]	[0]
BIT NAME							А	UXSC	AL [15:0	0]						
R/W		RW														
RESET																

BIT	BIT NAME	FUNCTION					
AUX_SCAL0 [7:0]	AUXSCAL	Sensitivity Calibration for AUXDATA.					
+ AUX_SCAL1 [7:0]	[15:0]	(Auxiliary calibration does not have temperature coefficient).					

AUX\_OCAL0 / AUX\_OCAL1 Register

Register Address: 0x3D / 0x3E, EEPROM Address: 0x02F / 0x030

				AUX_0	OCAL0				AUX_OCAL1							
		Register Address: 0x3D									Register Address: 0x3E					
		EEPROM Address: 0x02F									EEPROM Address: 0x030					
BIT	[7]	[7] [6] [5] [4] [3] [2] [1] [0]								[6]	[5]	[4]	[3]	[2]	[1]	[0]
BIT NAME							Α	UXOC	AL [15:	0]						
R/W		RW														
RESET									-							

BIT	BIT NAME	FUNCTION
AUX_OCAL0 [7:0]	AUXOCAL	Offset Calibration for AUXDATA.
+	[15:0]	(Auxiliary calibration does not have temperature coefficient.)
AUX_OCAL1 [7:0]	[10.0]	(Maxillary Calibration Good Not have temperature Coefficients)



**CHKSUM** Register

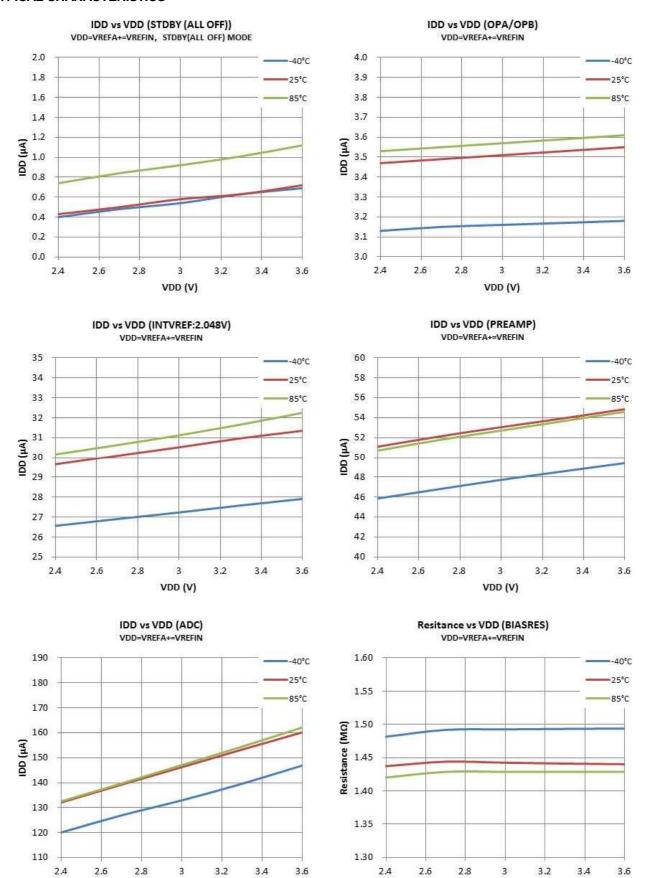
Register Address: 0x3F, EEPROM Address: -

CHKSUM								
BIT	[7] [6] [5] [4] [3] [2] [1] [0]							
BIT NAME	CHKSUM [7:0]							
R/W		R						
RESET	-							

BIT	BIT NAME	FUNCTION
[7:0]	CHKSUM	Check Sum value of register set value is showed which is read from external EEPROM.  Check Sum value is updated in following cases, when start up, when finish reading saved data from in external EEPROM, and when finish roading setting data to host-register from external EEPROM. Check Sum result value is finally showed as 1's complement. This result is summed unsigned data of each address byte (0x000 to 0x030) in external EEPROM.



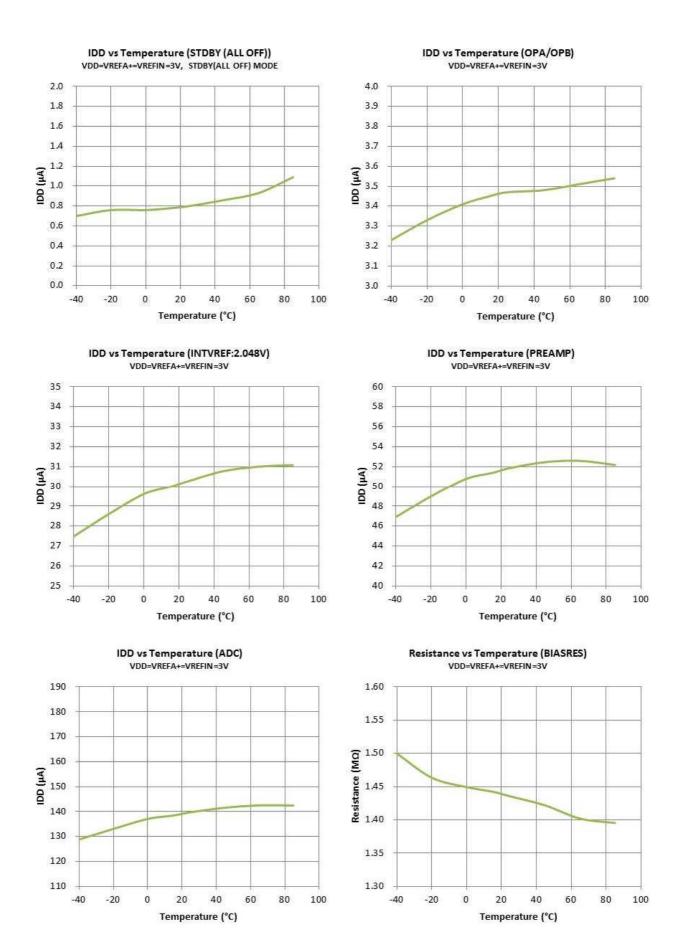
### **■TYPICAL CHARACTERISTICS**



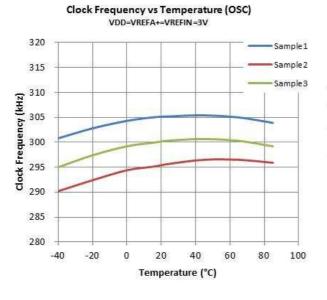
VDD (V)

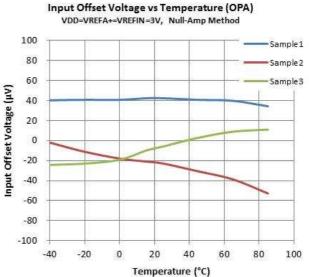
VDD (V)



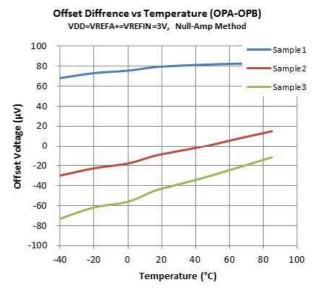


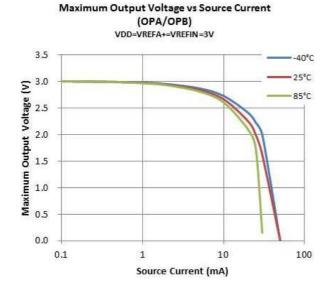


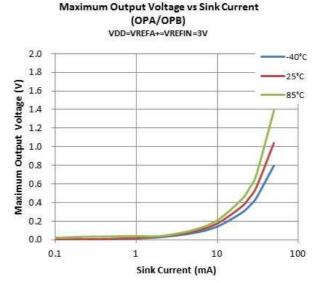




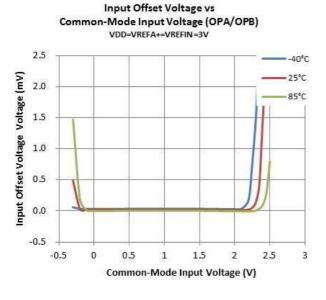
Input Offset Voltage vs Temperature (OPB) VDD=VREFA+=VREFIN=3V, Null-Amp Method 100 Sample 1 80 Sample 2 60 Sample 3 Input Offset Voltage (μV) 40 20 0 -20 -40 -60 -80 -100 -40 -20 0 20 40 60 80 100 Temperature (°C)

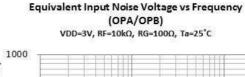


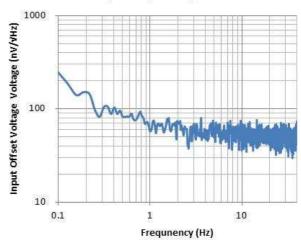


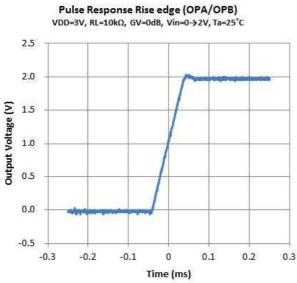




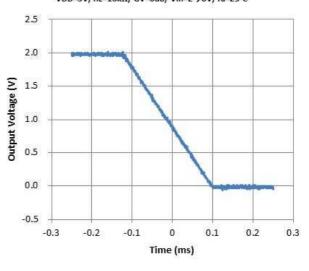


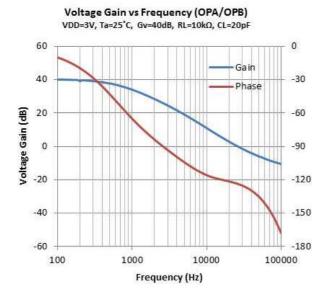




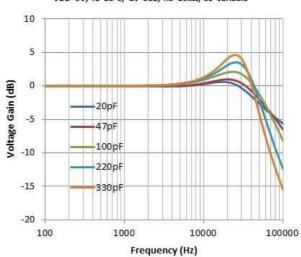


Pulse Response Fall edge (OPA/OPB) VDD=3V, RL=10kΩ, GV=0dB, Vin=2→0V, Ta=25°C

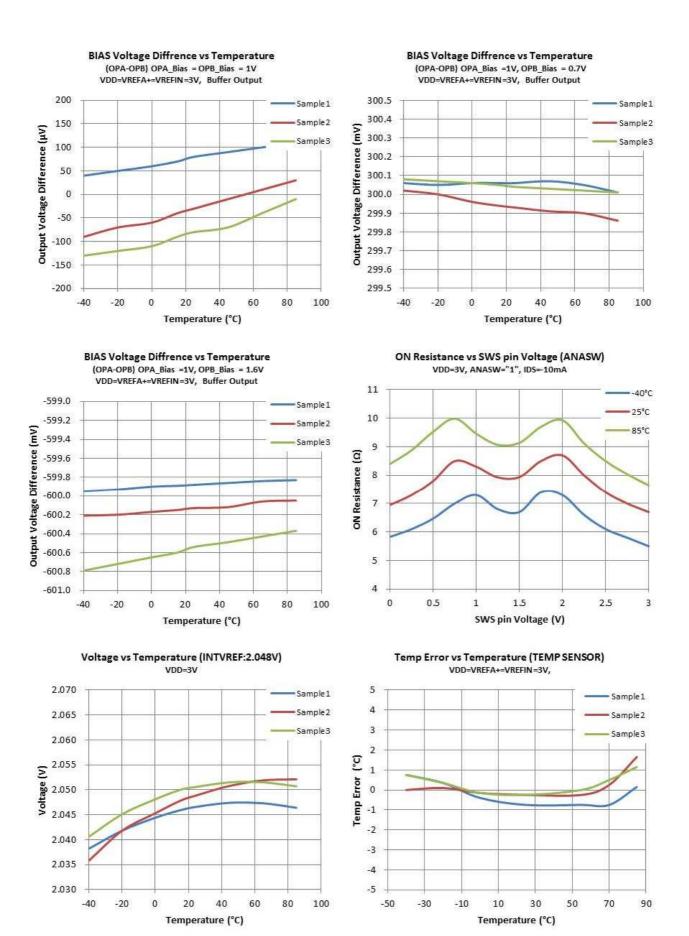




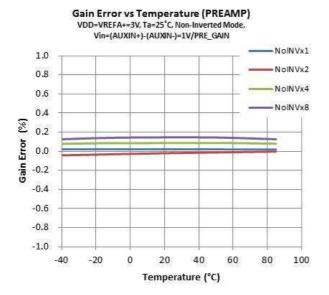
Voltage Gain vs Frequency (OPA/OPB) VDD=3V, Ta=25°C, Gv=0dB, RL=10kΩ, CL=variable

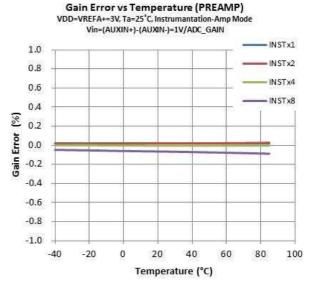


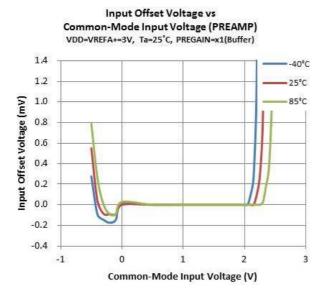


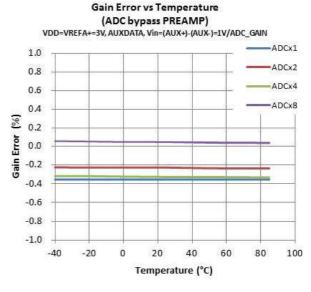


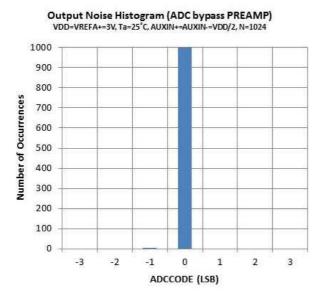


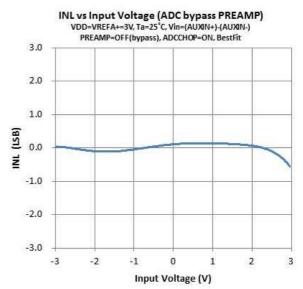














### **■APPLICATION NOTE / GLOSSARY**

NJU9101 consists of the following circuit block.

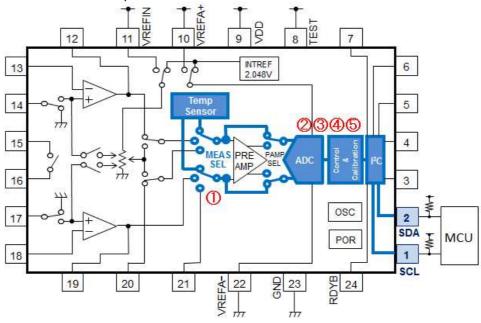
CIRCUIT BLOCK NAME	SYMBOL
2 Low Current Operational Amplifier	"OPA", "OPB"
Bias Level Setting Register	"BIASRES"
10Ω Analog Switch	"ANASW"
Variable Gain Pre-Amplifier	"PREAMP"
Temperature Sensor	"TempSensor"
Internal Reference	"INTVREF (2.048V)"
16-Bit sigma delta ADC	"16-Bit ADC"
Digital Control & Calibration	"Control&Calibration"
I <sup>2</sup> C Bus Compatible Control	"l <sup>2</sup> C"

NJU9101 is suitable for many kinds of low power analog signal applications by using these circuit blocks.

### 1. Signal channel selection for Measurement

### 1.1 Temperature Sensor Measurement

Write below code to measure Temperature.

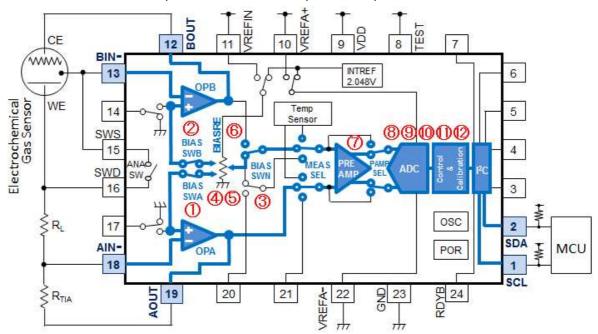


	No.	CONTENS	REGISTER ADDRESS	REGISTER NAME	BIT NAME	BIT	VALUE
	1	Select Temperature Input Mode			MEAS_SEL	[2:1]	00
	2	Select ADC Conversion Mode (Exp. Single Conversion)	0,,00	CTRL	MEAS_SC	[0]	0
Ī	3	Start AD Conversion	0x00				1
	4	Check completion of the AD conversion ("MEAS" bit = "0")			MEAS		-
	5	Acquire AD conversion data. (TMPDATA)	0x06 0x07	TMPDATA0 TMPDATA1	TMPDATA	[9:0]	-



### 1.2 System Example 1 (Potentiostat Measurement)

Write below code to constitute "potentiostat" and "trans-impedance-amplifier"

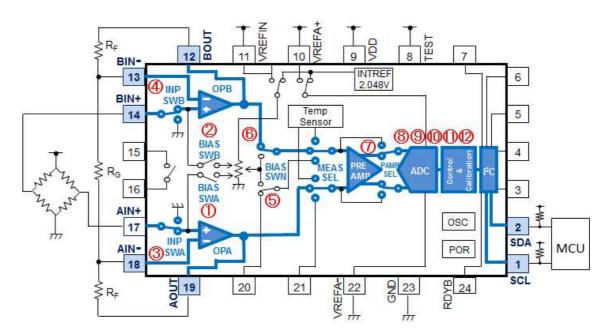


No.	CONTENS	REGISTER ADDRESS	REGISTER NAME	BIT NAME	BIT	VALUE
1	Connect the switch "BIASRES" and "OPA"	0x0F	BLKCONN0	BIASSWA	[5]	1
2	Connect the switch "BIASRES" and "OPB"	OXOF	BLRCONINO	BIASSWB	[4]	1
3	Select output of BIASRES	0x11	BLKCONN2	BIASSWN	[3]	1
4	Bias level for "trance-impedance-amplifier" (GND to 1.7V)	0x10 BLKCONN1		[7:5]		
5	Bias level for "potentiostat" (GND to 1.75V)	0x10	BLRCONNI	OPB_BIAS	[4:0]	any
6	Powered on BIASRES, OPA, OPB, OSC	0x12	BLKCTRL	BLKCTRL	[7:0]	0xF0
7	Enable PREAMP	0x11	BLKCONN2	PAMPSEL	[2]	1
8	Select Amp Input Mode			MEAS_SEL	[2:1]	01
9	Set Measurement Mode for ADC (ex.: Single conversion)			MEAS_SC	[0]	0
10	Start measurement	0x00	CTRL			1
11	Check completion of the AD conversion ("MEAS" bit = "0")			MEAS	[3]	-
12	Acquire AD conversion data	0x02	AMPDATA0	AMPDATA	[15:0]	-
12	(AMPDATA)	0x03	AMPDATA1	AIVIPDATA		



## 1.3 System Example 2 (Differential Input)

Write below code to constitute "Differential Amplifier Input" by using OPA/OPB.

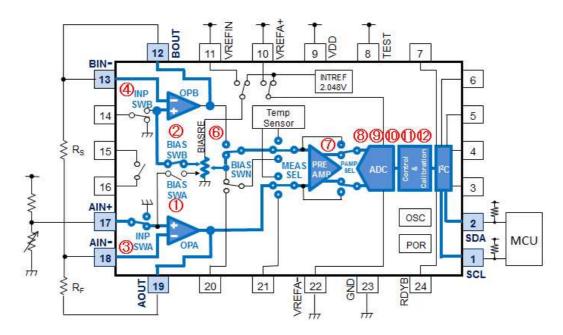


No.	CONTENTS	REGISTER ADDRESS	REGISTER NAME	BIT NAME	BIT	VALUE
1	Open OPA input switch	0x0F	BLKCONN0	BIASSWA	[5]	0
2	Open OPB input switch	OXOI	DLICONINO	BIASSWB	[4]	0
3	Select OPA sensor signal input			INPSWA	[6]	1
4	Select OPB sensor signal input	0x11	BLKCONN2	INPSWB	[5]	1
5	Select OPB output			BIASSWN	[3]	0
6	Powered on OPA, OPB, OSC	0x12	BLKCTRL	BLKCTRL	[7:0]	0x70
7	Enable PREAMP	0x11	BLKCONN2	PAMPSEL	[2]	1
8	Select Amp Input Mode			MEAS_SEL	[2:1]	01
9	Set Measurement Mode for ADC (ex.: Single conversion)	OTD.		MEAS_SC	[0]	0
10	Start measurement	0x00	CTRL	MEAS	[3]	1
11	Check completion of the AD conversion ("MEAS" bit = "0")					-
12	Acquire AD conversion data (AMPDATA)	0x02 0x03	AMPDATA0 AMPDATA1	AMPDATA	[15:0]	-



# 1.4 System Example 3 (Single Input (Non-Inverting))

Write below code to constitute "Single Amplifier Input" by using OPA/OPB.

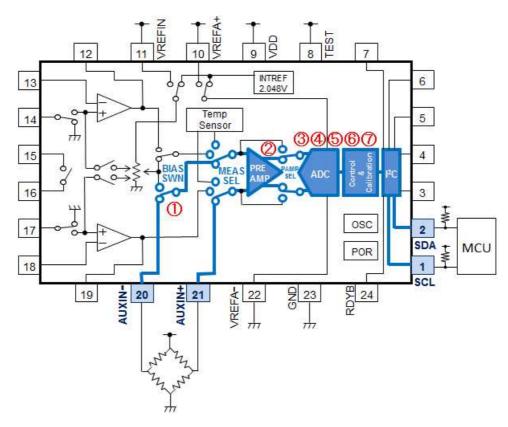


No.	CONTENTS	REGISTER ADDRESS	REGISTER NAME	BIT NAME	BIT	VALUE
1	Open OPA input switch	0x0F	BLKCONN0	BIASSWA	[5]	0
2	Close OPB input switch	UXUF	BLRCONNU	BIASSWB	[4]	1
3	Select OPA sensor signal input			INPSWA	[6]	1
4	Connect OPB positive input to GND	0x11	BLKCONN2	INPSWB	[5]	0
5	Select BIASRES output			BIASSWN	[3]	1
6	Powered on BIASRES, OPA, OPB, OSC	0x12	BLKCTRL	BLKCTRL	[7:0]	0xF0
7	Enable PREAMP	0x11	BLKCONN2	PAMPSEL	[2]	1
8	Select Amp Input Mode			MEAS_SEL	[2:1]	01
9	Set Measurement Mode for ADC (ex.: Single conversion)	0x00	CTRL	MEAS_SC	[0]	0
10	Start measurement	UXUU	CIRL			1
11	Check completion of the AD conversion ("MEAS" bit = "0")			MEAS	[3]	-
12	Acquire AD conversion data (AMPDATA)	0x02 0x03	AMPDATA0 AMPDATA1	AMPDATA	[15:0]	-



# 1.5 Auxiliary (external Input) Measurement

Write below code to constitute "Differential Amplifier Input" by using PREAMP.



No.	CONTENTS	REGISTER ADDRESS	REGISTER NAME	BIT NAME	BIT	VALUE
1	Select AUXIN input	0v11	BI KCONNIS	BIASSWN	[3]	1
2	Enable PREAMP	OXII	0x11 BLKCONN2		[2]	1
3	Select Auxiliary input mode			MEAS_SEL	[2:1]	10
4	Set Measurement Mode for ADC			MEAS SC	[0]	0
4	(ex.: Single conversion)		CTRL	MEAS_SC	[O]	U
5	Start measurement	0x00	CIKL			1
6	Check completion of the AD conversion			MEAS	[3]	
0	( "MEAS" bit = "0")					
7	Acquire AD conversion data	0x04	AUXDATA0	AUXDATA	[15:0]	
,	(AUXDATA)	0x05	AUXDATA1	AUNDATA	[15.0]	-



#### 2. Potentiostat & Ttans-impedance-amp circuit block

Potentiostat consists of "OPB", "Variable Bias Resister (BIASRES)". "Reference Electrode (RE)" bias voltage is set by "Variable Bias Resister (BIASRES)" using command in "OPB\_BIAS" bits. "Trans-impedance-amp(OPA)" connected to the "Working Electrode (WE)" is used to provide an output voltage that is proportional to the cell current. Bias Voltage of OPA is also set by BIASRES using command in "OPA\_BIAS" bits.

OPA gain is set by external resister (R<sub>TIA</sub>). And, please connect R<sub>L</sub> between WE and negative input of OPA.

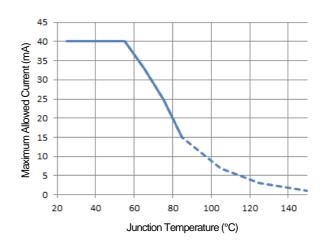
### 3. Shorting FET Function

NJU9101 has Internal Analog Switch (ANASW). This switch can connect between WE and RE of Chemical Sensor Cell. This Switch is switched on/off by "ANASW" bit.

In discrete system, depletion FET (ex. J177) is usually used as shorting FET. But, this switch "ANASW" in NJU9101 is enhancement FET (not depletion FET).

Therefore, this switch "ANASW" is effective only during powered on. This means that "ANASW" can't turn on during powered off.

ON resistance of this switch "ANASW" is  $10\Omega$  typ. This is to get a quick stabilized time after powered on.



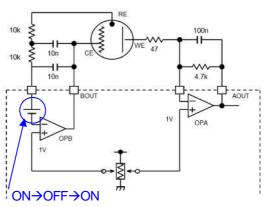
### 4. Regarding Sensor Diagnostic Function

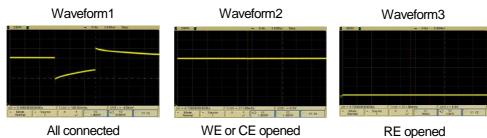
NJU9101 has Sensor Diagnostic Function using "SENSCK" bits.

When "SENSCK" mode turns ON ("1"), Offset Voltage of "OPA" changes around ±5mV. To switch "SENSCK" bits to "0"→"1"→"0", you can get as below waveforms.

\* This is one of way to Sensor Diagnostic that we propose only.

Sensor Condition	AOUT VO SENSCK OFF	oltage SENSCK ON	BOUT Condition
ALL connected	1V	0.6V	Waveform1
WE opened	1V	1V	Waveform2
CE opened	1V	1V	vvavelomiz
RE opened	0V	0V	Waveform3







## 5. Variable Bias Register (BIASRES)

"Variable Bias Resister (BIASRES)" for "OPA", "OPB", and "PREAMP" are shown in below.

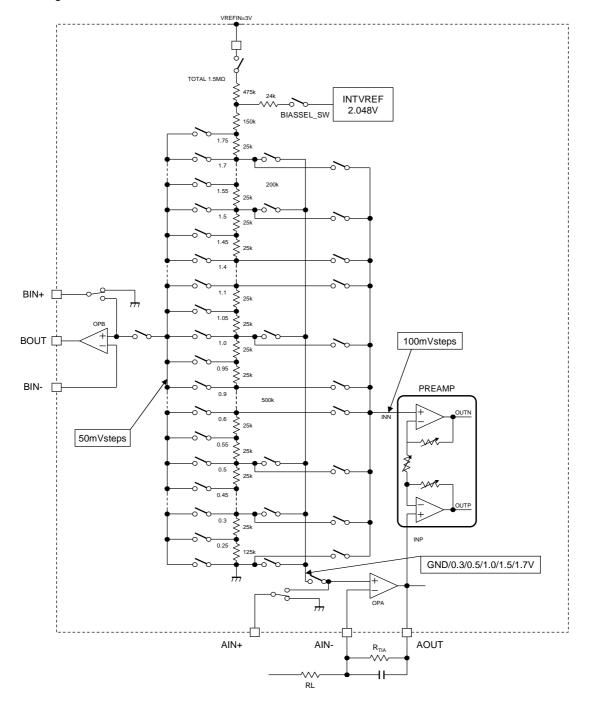
The Bias Voltage for these amplifiers are given by resister ladder ratio (total resister =  $1.5M\Omega$ ). These resister ladder ratio are set by "OPA\_BIAS", "OPB\_BIAS", "PRE\_BIAS" registers. Setting Name of these register (ex. 0.5V @ VREFIN=3V) is in VREFIN=3V condition.

If VREFIN is not 3V (ex. VREFIN=2.5V), the selected Voltage is shifted as follow.

If register setting is "1.5V @ VREFIN=3V"

Actual Voltage is 1.5V \* (2.5V/3.0V) = 1.25V

And, when "BIASSEL = 0", BIASSEL\_SW is turned on and fixed voltage "INTVREF (2.048V)" is given to the resister ladder shown in figure below.





### 6. PREAMP Gain Calculation

"Non-Inverted Amplifier" or "Instrumentation Amplifier" is selected by "PREMODE" bit.

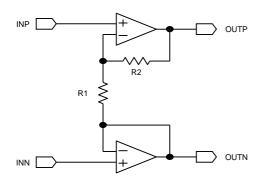
"Pre-Amplifier-Gain" is selected by "PRE\_GAIN" bits.

Input Voltage range of INP&INM is "0V" ~ "VDD-1V".

Output Voltage range of OUTP&OUTN is "0.05V" ~ "VDD-0.05V".

\* Please design not to exceed Input & Output Voltage range.

### 6.1. PREMODE = 0 (Non-Inverted Amplifier)



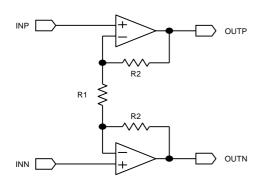
$$V(OUTP) = V(INP) + \frac{R2}{R1} \times V(INP - INN)$$

$$V(OUTN) = V(INN)$$

$$GAIN = \frac{V(OUTP - OUTN)}{V(INP - INN)} = 1 + \frac{R2}{R1}$$

Gain	PRE_GAIN	R1	R2
1 V/V	00	320kΩ	Ω0
2 V/V	01	160kΩ	160kΩ
4 V/V	10	80kΩ	240kΩ
8 V/V	11	40kΩ	280kΩ

### 6.2. PREMODE = 1 (Instrumentation Amplifier)



$$V(OUTP) = V(INP) + \frac{R2}{R1} \times V(INP - INN)$$

$$V(OUTN) = V(INN) + \frac{R2}{R1} \times V(INN - INP)$$

$$GAIN = \frac{V(OUTP - OUTN)}{V(INP - INN)} = 1 + 2 \times \frac{R2}{R1}$$

Gain	PRE_GAIN	R1	R2
1 V/V	00	320kΩ	0Ω
2 V/V	01	160kΩ	80kΩ
4 V/V	10	80kΩ	120kΩ
8 V/V	11	40kΩ	140kΩ



### 7. Low Power Management

NJU9101 is intended for use in portable devices, so the power consumption is as low as possible in order to ensure a long battery life. Following usage assumption of NJU9101 is in a portable gas detector. And its power consumption is summarized in below. The total power consumption for NJU9101 is below @3V average over time, this excludes any current drawn from any pin, please consider another device's consumption.

#### < Condition >

- ~ The system is used about 8 hours a day, and 16 hours a day it is in Standby mode.
- ~ Basically, Only "OPB" and "BIASRES" block are turned On in Standby mode.
- ~ Potentiostat Measurement is once per second.
- ~ Aux Data Measurement is one per minutes.
- ~ Temperature Measurement is one per minutes.
- ~ ADC conversion time uses approximately 16.6ms. (OSR="01", REJ="10", ADCCHOP="1")

	O: "	3-Lead	Potentiostat	Aux Data	Temperature	Total Current
	Standby	Potentiostat	Measurement	Measurement	Measurement	Consumption
Current Consumption	0.5µA	10.5μA	215.5µA	160.5µA	250.5µA	
	16 (h)	8 (h)	480 (s)	8 (s)	8 (s)	
Time On a Day	66.6%	33.3%	0.556%	0.009%	0.009%	
Average Current	0.33µA	3.5µA	1.2µA	0.01µA	0.02μΑ	<u>5.01μA</u>
ANASW	ON	OFF	OFF	OFF	OFF	
BIASRES	OFF	ON	ON	ON	ON	
OPA	OFF	ON	ON	ON	ON	
OPB	OFF	ON	ON	ON	ON	
PREAMP	OFF	OFF	ON	OFF	ON	
ADC	OFF	OFF	ON	ON	ON	
Temp. sensor	OFF	OFF	OFF	OFF	ON	
I <sup>2</sup> C & Logic	ON	ON	ON	ON	ON	

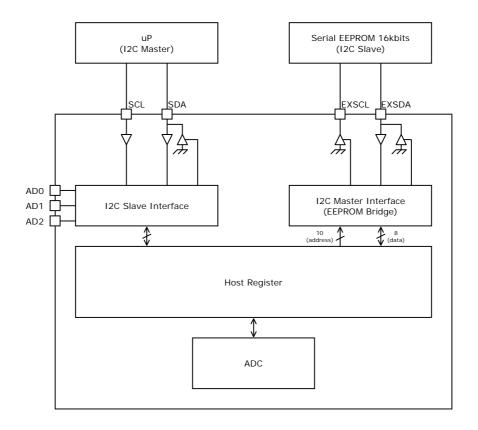


# 8. I<sup>2</sup>C-BUS Interface

NJU9101 has 2 types of I<sup>2</sup>C bus, one bus communicates to host device such as MCU, the other bus communicates to external EEPROM which is to retain the IC configurations, calibration parameters, .etc. These 2 types of I<sup>2</sup>C bus operate independently. NJU9101 operates for host interface as I<sup>2</sup>C slave device, and operates for EEPROM interface as I<sup>2</sup>C Master Device.

One I<sup>2</sup>C-bus which connects to host device is SCL/SDA, and the other I<sup>2</sup>C-bus which connects to external EEPROM is EXSCL/EXSDA.

Communicate	I <sup>2</sup> C bus	I/O	Master / Slave	
Host Device SCL		Input	NJU9101:Slave	
(e.g.: MPU)	SDA	Input / Open-Drain Output	NJUSTUT.Slave	
External EEPROM	EXSCL	Open-Drain Output	NJU9101:Master	
EXIEMAI EEPROW	EXSDA	Input / Open-Drain Output	NJU9101.IVIastei	



### 8.1. I<sup>2</sup>C Slave Interface

This interface is used for the Host that accesses to registers in NJU9101. NJU9101 is a  $I^2C$  Slave device for the host MCU. The operation of which conversion trigger, conversion data reading, access external EEPROM, .etc. are executed through reading and writing of registers in NJU9101. Registers in NJU9101 are register address  $0x00 \sim 0x3F$  and each address has 8 bits width register.



# • I<sup>2</sup>C Protocol

7bit-I<sup>2</sup>C Slave address consists of a fixed four-bit '0x9(b1001)' and chip address pin 'AD2', 'AD1', 'AD1'.

In case of write operation, transmit the writing data in following,

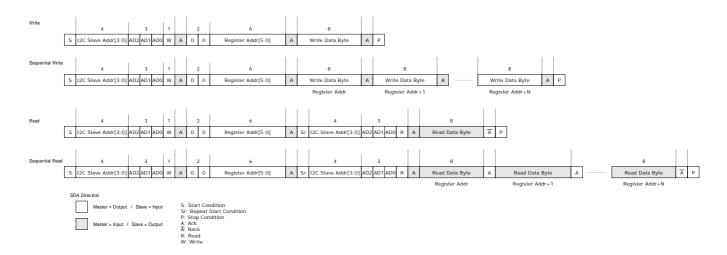
'Slave address' + 'Write bit (0)' + 'Write Register address' + 'Write data'.

When more than 2 bites of write data are transmitted, register address are increment automatically, and write the date into corresponding registers. When register address is over 0x3F, return to address 0x00 and lap around.

In case of read operation, transmit the data in following,

'Slave address' + 'Write bit (0)' + 'Read Register address' and then transmit 'repeat start' command.

When more than 2 bites of read data are read, register address are increment automatically, and read the date into corresponding address. When register address is over 0x3F, return to address 0x00 and lap around.



### • I<sup>2</sup>C external EEPROM Interface

I<sup>2</sup>C external EEPROM of 16k-Bit (2kByte) can be connected as a external storage device for NJU9101. 'Microchip 24LC16B' is used as a standard External EEPROM. Other I<sup>2</sup>C Serial EEPROM with communication compatible can be used. Some areas in external EEPROM are used as preset area for configuration data of NJU9101. The remaining areas in external EEPROM can be used for any uses.

NJU9101 supports 4-operations for external EEPROM from host-interface (MCU).

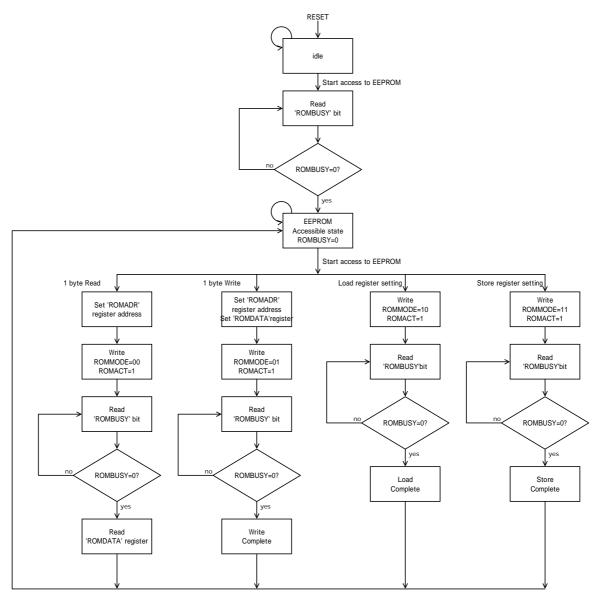
- · Read data from arbitrary address area in external EEPROM.
- · Write data to arbitrary address area in external EEPROM.
- · Load the all data from external EEPROM to host register (MCU).
- · Store register data in host register (MCU) to external EEPROM.

See also, "EVERY REGISTER DESCRIPTION: ROMCTRL" to control the external EEPROM.



## External EEPROM operating flow & External EEPROM I<sup>2</sup>C bus timing

Flow chart of access to external EEPROM is shown in below. When access to external EEPROM, system clock has to be operating and 'ROMBUSY' bit has to be '0'. And it can also access to external EEPROM under ADC conversion (Except for reading the initial register value just after reset release.).



External EEPROM requires about 5ms of write time internally after write operation. During this period, NJU9101 cannot read/write from/to external EEPROM and external EEPROM returns 'NACK' for address byte. When NJU9101 starts to access to external EEPROM, NJU9101 does polling until receive 'ACK', and wait for completion of writing time in external EEPROM.

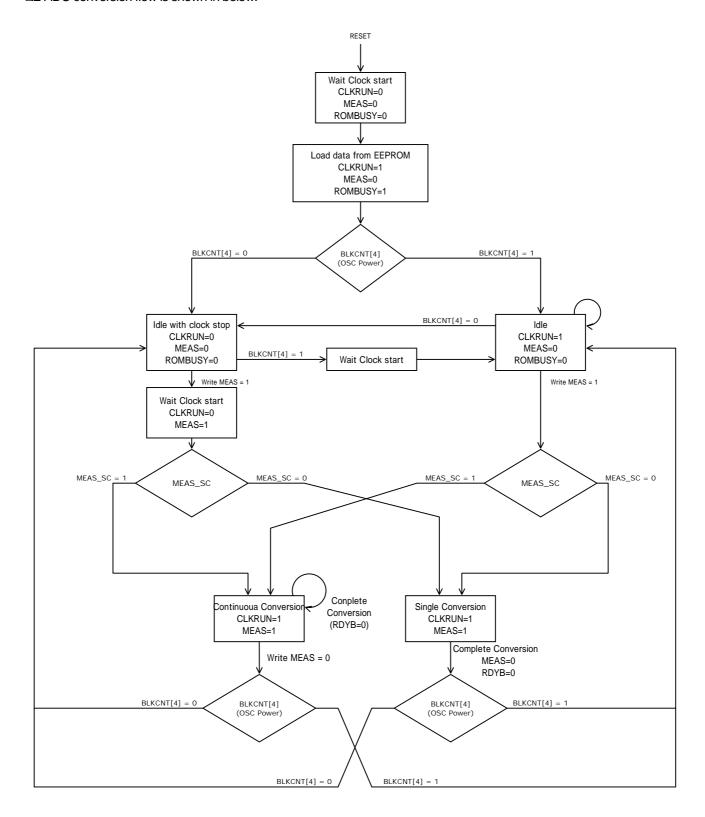
When NJU9101 is not connected with external EEPROM, address byte of NJU9101 always receives 'NACK'. Therefore, External EEPROM Control block in NJU9101 cannot stop polling. In such case, stop accessing to external EEPROM quickly by writing "1" to "ROMSTOP" bit, or it can break out of the polling by generating communication error ("ROMERR"="1") with fixed "0" for EXSDA terminal.

I<sup>2</sup>C-bus of external EEPROM uses 3-system clock every 1 bit transfer, therefore maximum translate is fin/3[bps].



### ΔΣ ADC control

 $\Delta\Sigma$  ADC conversion flow is shown in below.





#### • Start-Up

After power-on reset or release I<sup>2</sup>C reset, start internal clock (OSC) and load data from external EEPROM to NJU9101's register. During loading, 'ROMBUSY' shows '1'. After finish loading to NJU9101's register, NJU9101 becomes idle state or idle state with clock stop which are following BLKCNT [4] setting.

#### • Idle State

"Idle state" means in the state which is not conversion state. In the idle state, 'BLKCNT [4](OSC power down)'bit changes the powered-on/off of system clock. During stopping the system clock, NJU9101 is idle state with clock stop, and it cannot write the data of NJU9101 register except 'CTRL' and 'BLKCNT' register. This means that "Please write 'BLKCNT[4]'='1', when change the data of NJU9101 register".

#### • Conversion

When write 'MEAS' bit = '1', conversion starts with following NJU9101 register setting.

First, Wake up time of modulator T<sub>wu</sub> is required after conversion started.

$$T_{WU} = 20 / f_{mod}$$
 [sec]

 $T_{adc}$  is the time which is divided 'decimation rate (set in OSR / REJ bit) by  $f_{mod}$  (normal modulation clock frequency of  $\Delta\Sigma$  modulator  $\approx$  153.6 kHz).

$$T_{adc}$$
 = Decimation rate /  $f_{mod}$  [sec]

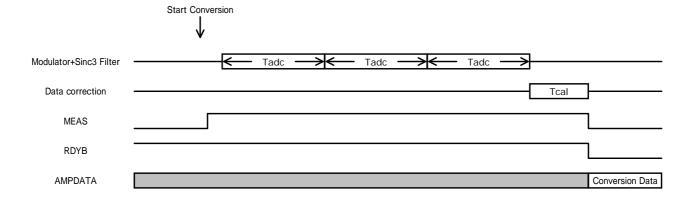
Standard timing of ADC conversion is defined as Tadc.

And, after completion of conversion, it requires around 70 cycle of system clock  $(70 \, / \, f_{OSC})$  to do data corrective calculation. This calculation time is defined as  $T_{cal}$ .

$$T_{cal} = 70 / f_{OSC} \approx 230 \mu$$
 [sec]

#### • Single Conversion

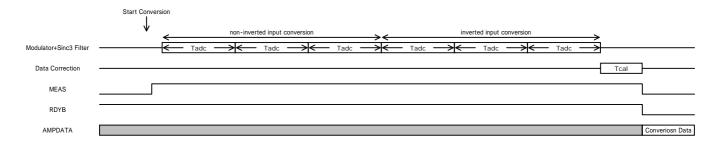
Conversion time of 'Single conversion' is ' $T_{wu} + 3 * T_{adc} + 'T_{cal}$ '. The settling time of ADC requires ' $3 * T_{adc}$ '. After complete data correction, data register is updated, and RDYB bit is asserted.





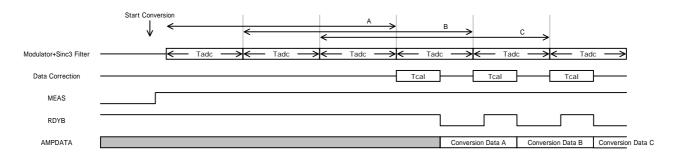
### • Single Conversion + Chopping Operation

Conversion time of 'Single Conversion + Chopping Operation' is ' $T_{wu}$  + 6 \*  $T_{adc}$  +  $T_{cal}$ '. The settling time of ADC requires '6 \*  $T_{adc}$ '. After complete data correction, data register is updated, and 'RDYB' bit is asserted. And then, 'MEAS' bit turns to '0', become idle state again. Chopping operation can cancel offset voltage into ADC by swapping differential positive - negative input.



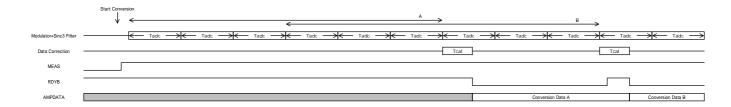
#### Continuous Conversion

The first conversion time of 'Continuous Conversion' is ' $T_{wu} + 3 * T_{adc} + T_{cal}$ '. The settling time of ADC requires  $T_{adc}$ . After complete the first conversion data correction, data register is updated, and RDYB bit is asserted. And after that, data register is updated and RDYB bit is asserted every  $T_{adc}$ . Conversion rate after the first conversion is 1/Tadc [sps]. This conversion is continued until written 'MEAS = 0'.



#### • Continuous Conversion + Chopping Operation

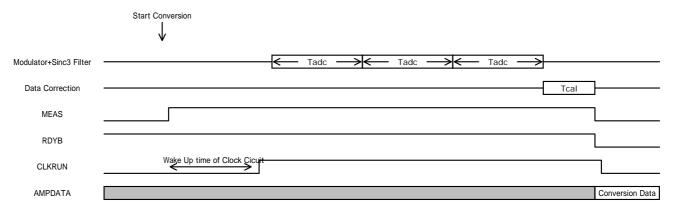
The first conversion time of 'Continuous Conversion + Chopping Operation' is ' $T_{wu}$  + 6 \*  $T_{adc}$  +  $T_{cal}$ . The settling time of ADC requires '6 \*  $T_{adc}$ '. After complete data correction, data register is updated, and RDYB bit is asserted. And after that, data register is updated and RDYB bit is asserted every '3 \*  $T_{adc}$ '. Conversion rate after the first conversion is '1/(3 \*  $T_{adc}$ )' [sps]. This conversion is continued until written 'MEAS = 0'.





## • Conversion at 'Idle state with Clock Stop'

In case of 'Idle state with Clock Stop (BLKCNT[4]=0)', it is necessary an additional time ( $\approx$ 450us) to wake up the clock circuit after start conversion trigger. When 'Single Conversion' is set, it turns 'Idle state with Clock Stop (BLKCNT [4] = 0)' automatically after complete the conversion.



#### • Power-Down Control

Power down control signal of each circuit block in NJU9101 is controlled by following registers value 'MEAS', 'MEAS\_SEL', 'VREFSEL', 'PAMPSEL', and 'BLKCNT[7:0]'.

### **BIASRES** circuit block power down

Dlook	BLKCNT	Power	
Block	[7]	Condition	
BIASRES	0	PWR DOWN	
DIAGREG	1	OPERATE	

### **OPA circuit block power down**

Block	MEAS	MEAS_SEL [1:0]	BLKCNT [5]	Power Condition
	0	-	0	
ODA	1	00 / 10	0	PWR DOWN
OPA	1	01	0	OPERATE
	-	-	1	OPERATE

# **OPB circuit block power down**

		i i	*	
Block	MEAS	MEAS_SEL	BLKCNT	Power
	IVIEAS	[1:0]	[6]	Condition
ОРВ	0	-	0	PWR DOWN
	1	00 / 10	0	FWK DOWN
	1	01	0	OPERATE
	-	-	1	OFERAIE



# OSC circuit block power down

Block	MEAS	BLKCNT [4]	BLKCNT [1]	Power
	MEAS -	OSC	ADC	Condition
	0	0	0	PWR DOWN
OSC	1	0	0	
USC	-	1	-	OPERATE
	-	-	1	

# PREAMP circuit block power down

Block	MEAS	MEAS_SEL [1:0]	PAMPSEL	BLKCNT	Power Condition
		[1.0]		[3]	
	0	-	-	0	PWR DOWN
	1	00	-	1	OPERATE
PREAMP	1	01 / 10	0	0	PWR DOWN
	1	01 / 10	1	0	OPERATE
	-	-	-	1	OFERATE

# 2.048V INTVREF circuit block power down

Block	MEAS	MEAS_SEL [1:0]	BIASSEL	VREFSEL	BLKCNT [2]	Power Condition
	0	-	1	ı	0	PWR DOWN
	1	00	1	-	0	OPERATE
INTVREF	1	01 / 10	1	0	0	
INIVE	1	01 / 10	1	1	0	PWR DOWN
	-	-	1	-	1	OPERATE
		-	0	1	. 1	OFERATE

# ADC circuit block power down

Dlask	MEAC	BLKCNT	Power
Block	IVIEAS	[1]	Condition
	0	0	PWR DOWN
ADC	1	0	OPERATE
	0 [1]	OPERATE	

# Temperature Sensor circuit power down

Block	MEAS	MEAS_SEL	BLKCNT	Power
DIUCK	IVIEAS	[1:0]	[0]	Condition
	0	-	0	PWR DOWN
Temp.	1	00	0	OPERATE
Sensor	1	01 / 10	0	PWR DOWN
	-	-	1	OPERATE



### Data Processing

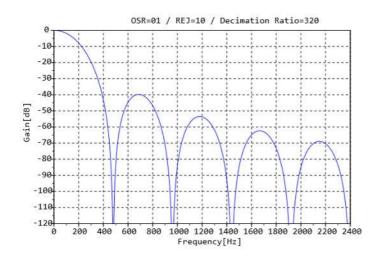
Analog Input is modulated to PDM signal by  $2^{nd}$  Order  $\Delta\Sigma$  modulator. And then, this PDM signal changes to PCM signal by Sinc3 Digital Filter. Sinc3 Digital Output data is stored to AMPDATA / AUXDATA / TMPDATA register after data calibration.

#### ΔΣ Modulator

Normal modulation clock frequency of  $\Delta\Sigma$  (Sigma Delta) modulator (fmod) is 153.6 kHz. This frequency (fmod) is the over-sampling clock of the ADC which is divided OSC system clock ( $f_{OSC}$ ) with setting of 'CLKDIV' bit. Modulated ratio of this modulator is 66.7%. When +1.5Vpp of differential signal is input, modulated output goes to +1Vpp.

### Sinc3 Digital Filter

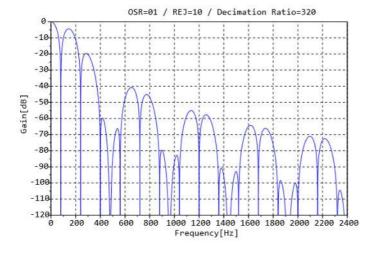
Digital Filter in NJU9101 is 3<sup>rd</sup> Order Sinc-Filter that has 768 of maximum decimation ratio. This decimation ratio can be set by 'OSR' and 'REJ' bit.



■ Sinc3 filter frequency example 1 (CHOPPING OFF setting example)

Conversion Time = 7.5ms (Single conversion)

Decimation Ratio=320 (OSR=01, REJ=10, CLKDIV=00, ADCCHOP=0)

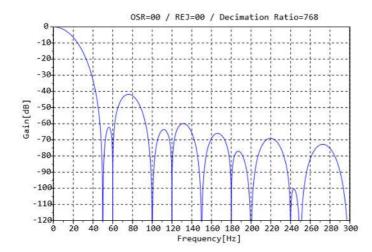


■ Sinc3 filter frequency example 2 (CHOPPING ON setting example)

Conversion Time = 13.8ms (Single conversion)

Decimation Ratio = 320 (OSR=01, REJ=10, CLKDIV=00, ADCCHOP=1)

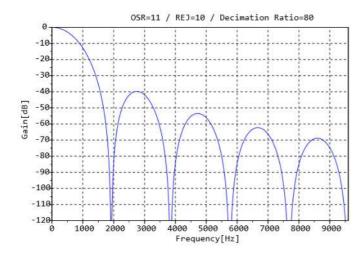




■ Sinc3 filter frequency example 3 (50 / 60Hz Reduction setting example)

Conversion Time = 61.6ms (Single Conversion)

Decimation Ratio = 768 (OSR=00, REJ=00, CLKDIV=10, ADCCHOP=0)



■ Sinc3 filter frequency example 4 (Fastest Conversion Time setting example)

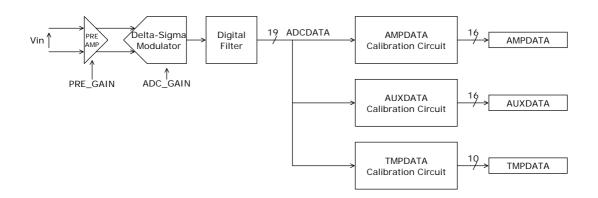
Conversion Time = 2.8ms (Single Conversion)

Decimation Ratio = 80 (OSR=11, REJ=10, CLKDIV=00, ADCCHOP=0)



#### Data Calibration

Analog Input is modulated to PDM signal by  $2^{nd}$  Order  $\Delta\Sigma$  modulator. And then, this PDM signal is changed to signed 19 bit PCM signal (ADCDATA) by Sinc3 Digital Filter. The full-scale range of ADCDATA is -262144  $\sim$  +26143 (0x40000  $\sim$  0x3FFFF). ADCDATA is stored to AMPDATA / AUXDATA / TMPDATA register after data calibration.



Regarding calculation of ADCDATA, Voltage GAIN of PREAMP (G<sub>pre</sub>) and Conversion GAIN of ADC (G<sub>adc</sub>) are defined as below,

Gain of PREAMP

PAMPSEL	PRE_GAIN	G <sub>pre</sub>
0	XX	1
1	00	1
1	01	2
1	10	4
1	11	8

Gain of ADC

ADC_GAIN	G <sub>adc</sub>
00	1
01	2
10	4
11	8

When it is assumed that

"Vref": Reference Voltage selected by "VREFSEL"bit.

"Vin" :Differential Input Voltage of PREAMP

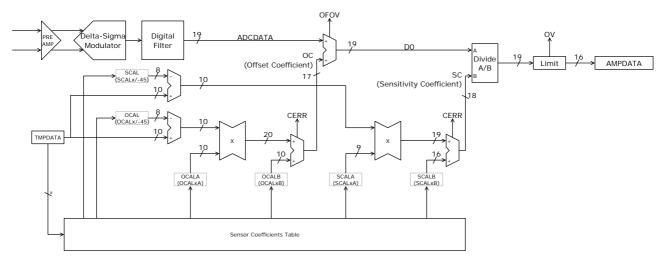
Digital Filter Output (ADCDATA) is output as below, when ADCDATA range is limited as signed 19 bit range (min:-262144(0x40000), max:+262143(0x3FFFF).

$$\text{ADCDATA} = 262144 \times G_{pre} \times G_{adc} \times \frac{2}{3} \times \frac{V_{in}}{V_{ref}}$$



#### AMPDATA Calibration

AMPDATA Calibration has temperature calibration of offset and Sensitivity for ADCDATA. And then, calibrated data is stored to AMPDATA[15:0] register. AMPDATA calibration path is shown in below.



Calibration coefficients for offset are set for four temperature areas. For these temperature areas, 0-order coefficient (offset value: OCALxB at OCALx[°C]) and 1<sup>st</sup>-order coefficient (temperature slope: OCALxA) are set. These temperature area are set by OCALx[°C] (-45°C ≤ OCAL1 < OCAL2 < OCAL3 ≤ 127°C). These coefficients are automatically selected by TEMPDATA value. Offset Calibration coefficient "OC" is signed 17-bits factor and calculated as below

Condition	Calculation
-45 ≤ TEMPDATA [9:2] < OCAL1	OC = [ {TEMPDATA - (-45 x 4) } x OCAL1A ] + (OCAL1B x 4)
OCAL1 ≤ TEMPDATA [9:2] < OCAL2	OC = [ {TEMPDATA - (OCAL1 x 4) } x OCAL2A ] + (OCAL2B x 4)
OCAL2 ≤ TEMPDATA [9:2] < OCAL3	OC = [ {TEMPDATA - (OCAL2 x 4) } x OCAL3A ] + (OCAL3B x 4)
OCAL3 ≤ TEMPDATA [9:2]	OC = [ {TEMPDATA - (OCAL3 x 4) } x OCAL4A ] + (OCAL4B x 4)

<sup>\*</sup> When "OC" value exceeds signed 17-bits range (-65536  $\sim$  +65535 (0x10000  $\sim$  0x0FFFF)), "CERR" bit is set as error flag of offset calibration coefficient. In this situation, AMPDATA is not correct value.

And then, ADCDATA and offset coefficient "OC" are summed. Converted DATA "D0" is calculated as below,

$$D0 = ADCDATA + (OC \times 4)$$

Calibration coefficients for sensitivity are set for four temperature areas. For these temperature areas, 0-order coefficient (sensitivity value: SCALxB at SCALx[°C]) and 1 $^{st}$ -order coefficient (temperature slope: SCALxA) are set. These temperature area are set by SCALx[°C] (-45 $^{\circ}$ C  $\leq$  SCAL1 < SCAL2 < SCAL3  $\leq$  127 $^{\circ}$ C). These coefficients are automatically selected by TEMPDATA value. Sensitivity Calibration coefficient "SC" is unsigned 18-bits factor and calculated as below.

<sup>\*</sup> When "D0" value exceeds signed 19-bits range (-262144 ~ +262143 (0x40000 ~ 0x3FFFF)), "OFOV" bit is set as error flag. In this situation, AMPDATA is not correct value.



Condition	Caluculation
-45 ≤ TEMPDATA [9:2] < SCAL1	SC = [ {TEMPDATA - (-45 x 4) } x SCAL1A ] + (SCAL1B x 4)
SCAL1 ≤ TEMPDATA [9:2] < SCAL2	SC = [ {TEMPDATA - (SCAL1 x 4) } x SCAL2A ] + (SCAL2B x 4)
SCAL2 ≤ TEMPDATA [9:2] < SCAL3	SC = [ {TEMPDATA - (SCAL2 x 4) } x SCAL3A ] + (SCAL3B x 4)
SCAL3≤TEMPDATA [9:2]	SC = [ {TEMPDATA - (SCAL3 x 4) } + (SCAL4B x 4)

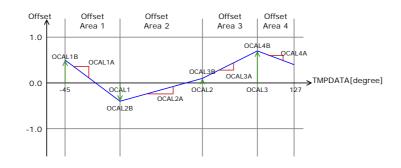
\* When "SC" value exceeds the range of  $8192 \sim 262143$  (0x2000  $\sim 0x3FFFF$ ), "CERR" bit is set as error flag of sensitivity calibration coefficient. In this situation, AMPDATA is not correct value. And when "SC" value is regarded as signed 2.16 fixed point, this data range is equivalent to  $4.0 \sim 0.125$ .

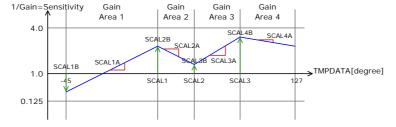
For Sensitivity calculation, offset conversion data "D0" is divided by "SC". This result (quotient) is rounded to integer, and then, AMPDATA is decided.

$$AMPDATA = Round \left( \frac{D0 \times 2^{14}}{SC} \right)$$

\* When AMPDATA value exceeds signed 16-bits range (-32768 ~ +32767 (0x8000 ~ 0x7FFF)), "OV" bit is set as error flag. In this situation, ADCDATA value is limited to min: -32768(0x8000) or max: +32767(0x7FFF), and then stored to AMPDATA register.

		Register	Calibration Range		Set Resolution	
		Register	±1.0 conv.	14-Bit conv.	±1.0 conv.	14-Bit conv.
Offse	t coef.					
	O <sup>th</sup>	OCALxB	±1.0	±8192	1 / (2^14)	0.5LSB
	1 <sup>st</sup>	OCALxA	±0.03125/°C	±256LSB/°C	1 / (2 to 14) / °C	0.5LSB/°C
Sens	coef.					
	O <sup>th</sup>	SCALxB	x0.125 to x4.0	-	61ppm	-
	1 <sup>st</sup>	SCALxA	±15625ppm / °C	-	61ppm / °C	-

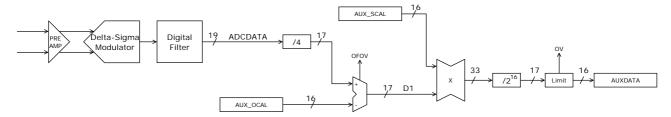






#### AUXDATA Calibration

AUXDATA Calibration has offset and Sensitivity calibration for ADCDATA. And then, calibrated data is stored to AUXDATA[15:0] register. AUXDATA calibration path is shown in below.



Conversion Data "D1" after offset calibration is calculated as below. (Low order 2-bit of ADCDATA are rounded down)

$$D1 = Truncate(\frac{ADCDATA}{4}) - AUX_OCAL$$

\* When "D1" value exceeds signed 17-bits range (-65536 ~ +65535 (0x10000 ~ 0x0FFFF)), "OFOV" bit is set as error flag. In this situation, AUXDATA value is not correct value.

For sensitivity calibration, it is multiplied conversion data "D1" by "AUX\_SCAL" coefficient. This result (product) is divided by 2^16, and is rounded to integer. And then, AMPDATA is decided.

$$AUXDATA = Round(\frac{D1 \times AUX\_SCAL}{2^{16}})$$

\* When AUXDATA value exceeds signed 16-bits range (-32768 ~ +32767 (0x8000 ~ 0x7FFF)), "OV" bit is set as error flag. In this situation, ADCDATA value is limited to min: -32768(0x8000) or max: +32767(0x7FFF), and then stored to AUXDATA register.

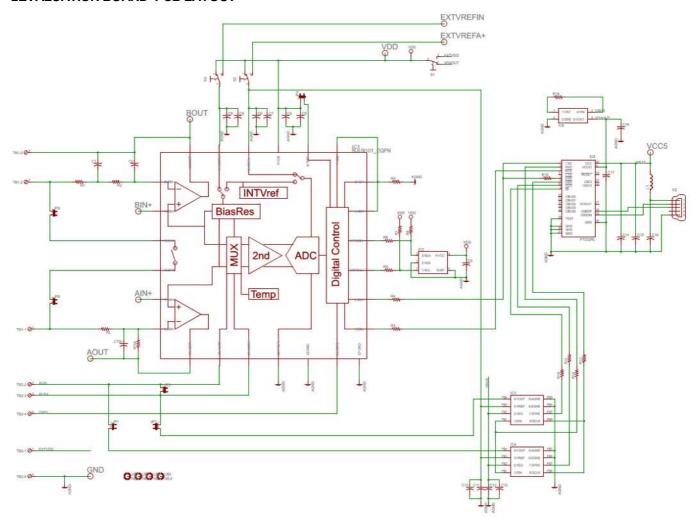
Dogistor		Calibration Range		Set Resolution	
	Register	±1.0 conv. 14-Bit conv.		±1.0 conv.	14-Bit conv.
Offset calibration coef.	AUX_OCAL	±0.5	±4096	1 / (2^17)	0.125LSB
Sensitivity calibration coef.	AUX_SCAL	x0.0 to x2.0	-	30.5ppm / °C	-

#### **TMPDATA Calibration**

TMPDATA data conversion are converted ADCDATA to temperature code. In TMPDATA conversion, fixed setting of these bits "VREFSEL", "ADC\_GAIN", PRE\_GAIN" are used. TMPDATA is converted to signed 10-bits data shown as 0.25°C/LSB. The data range of TMPDATA is -45.00°C ~ +127.75°C (0x34C ~ 0x1FF). When converted value exceeds this range, "OV" bit is set as error flag. In this situation, ADCDATA value is limited to min: -45.00°C (0x34C) or max: +127.75°C (0x1FF), and then stored to TMPDATA register.



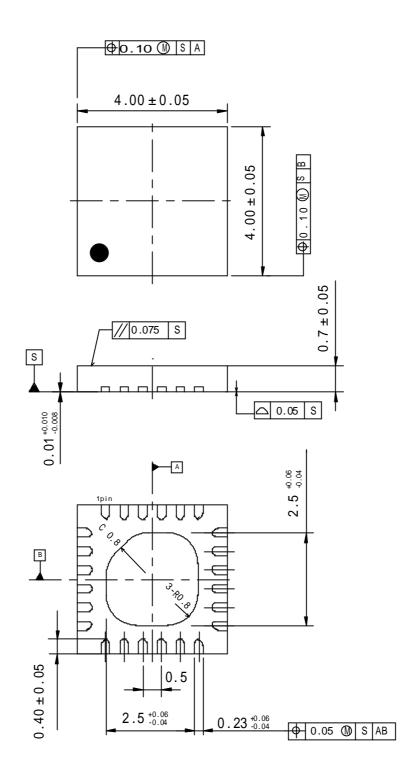
# ■EVALUATION BOARD · PCB LAYOUT



(Note) Install the decoupling capacitor in the proximity of the NJU9101.

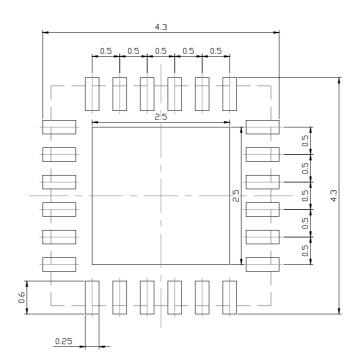


# ■PACKAGE OUTLINE EQFN-24-LE





# ■SOLDER FOOT PRINT EQFN-24-LE

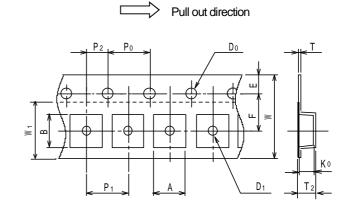




## **■PACKING SPECIFICATION**

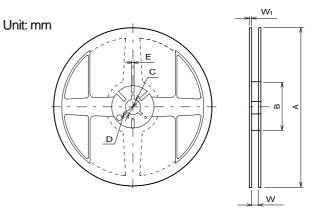
EQFN Emboss Taping (TE1)

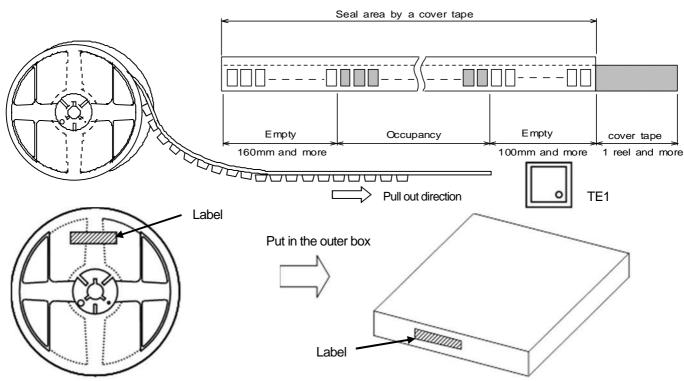
Symbol	EQFN18-E7	EQFN24-LK	EQFN24-LE	Remark
А	2.25±0.05	4.35±0.05	4.35±0.05	Bottom size
В	2.25±0.05	4.35±0.05	4.35±0.05	Bottom size
D <sub>0</sub>	1.5 +0.1/-0	1.5 +0.1/-0	1.5 +0.1/-0	
D <sub>1</sub>	0.5±0.1	1.0±0.1	1.0±0.1	
E	1.75±0.1	1.75±0.1	1.75±0.1	
F	3.5±0.05	5.5±0.05	5.5±0.05	
P <sub>0</sub>	4.0±0.1	4.0±0.1	4.0±0.1	
P <sub>1</sub>	4.0±0.1	8.0±0.1	8.0±0.1	
P <sub>2</sub>	2.0±0.05	2.0±0.05	2.0±0.05	
Т	0.25±0.05	0.3±0.05	0.3±0.05	
T <sub>2</sub>	1.0±0.07	1.3±0.07	1.3±0.07	
K <sub>0</sub>	0.65±0.05	-	-	
W	8.0±0.2	12.0±0.3	12.0±0.3	
W <sub>1</sub>	5.5	9.5	9.5	Thickness 0.1MAX



Symbol	EQFN18-E7	EQFN24-LK	EQFN24-LE
Α	Ø 180 +0/-1.5	Ø 180	+0/-1.5
В	Ø 60 +1/-0	Ø 60	+1/-0
$D_0$	Ø 13±0.2	Ø 13	3±0.2
D <sub>1</sub>	Ø 21±0.8	Ø 21 ± 0.8	
Е	2.0±0.5	2.0±0.5	
W	9.0 +0.3/-0	13.0 +1.0/-0	
$W_1$	1.2	1.2	
Contents	3,000pcs	1,000pcs	

Unit: mm

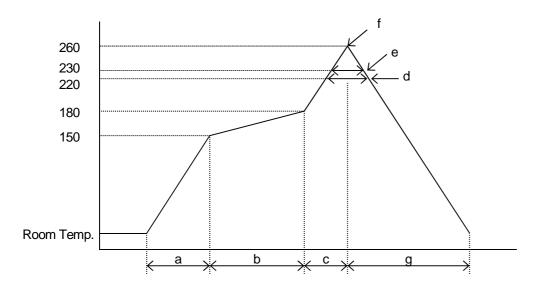






## **■RECOMMENDED MOUNTING METHOD**

\* Recommended reflow soldering procedure



a:Temperature ramping rate :1 to 4 /s : 150 to 180 b: Pre-heating temperature : 60 to 120s time c: Temperature ramp rate :1 to 4 /s : Shorter than 60s d:220 or higher time : Shorter than 40s e:230 or higher time : Lower than 260 f:Peak temperature g:Temperature ramping rate :1 to 6 /s

The temperature indicates at the surface of mold package.



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- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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